DATA SHEET

mos integrated circuit μ**PD784035, 784036, 784037, 784038**

16/8-BIT SINGLE-CHIP MICROCONTROLLER

The μ PD784038 is a product of the μ PD784038 sub-series in the 78K/IV series. It contains various peripheral hardware such as ROM, RAM, I/O ports, 8-bit resolution A/D and D/A converters, timers, serial interface, and interrupt functions, as well as a high-speed, high-performance CPU.

In addition, the μ PD78P4038 (one-time PROM or EPROM product), which can be operated within the same power supply voltage ranges as masked-ROM products, and development tools are supported.

For specific functions and other detailed information, consult the following user's manual. This manual is required reading for design work.

 μ PD784038, 784038Y Sub-Series User's Manual, Hardware : U11316E 78K/IV Series User's Manual, Instruction : U10905E

FEATURES

JEC

- Pin-compatible with the μPD78234, μPD784026, and μPD784038Y sub-series
- Expanded internal memory spaces in the μPD78234 and μPD784026 sub-series
- Minimum instruction execution time: 125 ns (at 32 MHz)
- Number of I/O ports: 64
- Timer/counters: 16-bit timer/counter \times 3 units 16-bit timer \times 1 unit
- A/D converter: 8-bit resolution × 8 channels
- D/A converter: 8-bit resolution \times 2 channels

- Serial interface: 3 channels
 UART/IOE (3-wire serial I/O): 2 channels
 CSI (3-wire serial I/O, 2-wire serial I/O): 1 channel
- PWM outputs: 2
- Standby function HALT/STOP/IDLE mode
- Clock frequency division function
- Watchdog timer: 1 channel
- Clock output function Selectable from fcLK, fcLK/2, fcLK/4, fcLK/8, or fcLK/16
- Supply voltage: VDD = 2.7 to 5.5 V

APPLICATIONS

LBP, automatic-focusing camera, PPC, printer, electronic typewriter, air conditioner, electronic musical instruments, cellular telephone, etc.

This manual describes the μ PD784038 unless otherwise specified.

The information in this document is subject to change without notice.

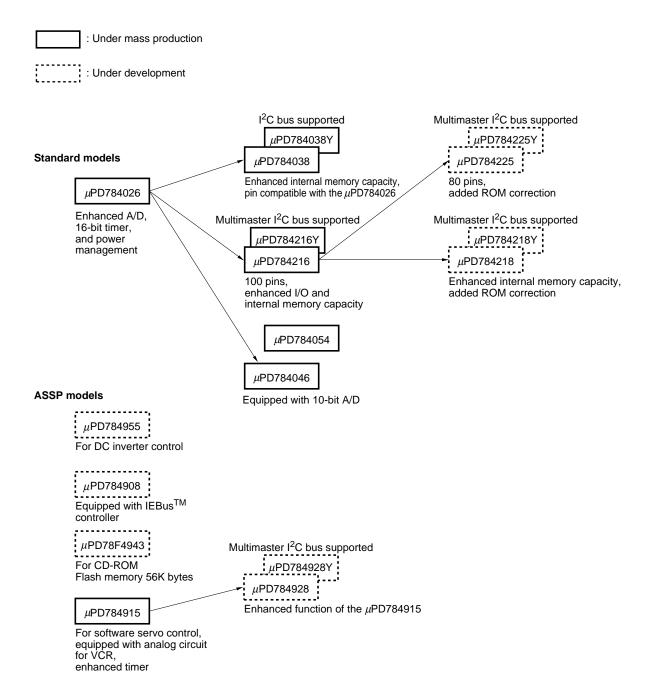
ORDERING INFORMATION

	Part number	Package	Internal ROM (bytes)	Internal RAM (bytes)
$\overline{\mu}$ F	D784035GC-xx-3B9	80-pin plastic QFP (14 $ imes$ 14 $ imes$ 2.7 mm)	48K	2,048
μF	D784035GC-xxx-8BT	80-pin plastic QFP (14 $ imes$ 14 $ imes$ 1.4 mm)	48K	2,048
μF	D784035GK-xxx-BE9	80-pin plastic TQFP (fine pitch) (12 $ imes$ 12 mm)	48K	2,048
μF	D784036GC-xxx-3B9	80-pin plastic QFP (14 $ imes$ 14 $ imes$ 2.7 mm)	64K	2,048
μF	D784036GC-xxx-8BT	80-pin plastic QFP (14 $ imes$ 14 $ imes$ 1.4 mm)	64K	2,048
μF	D784036GK-xxx-BE9	80-pin plastic TQFP (fine pitch) (12 $ imes$ 12 mm)	64K	2,048
* μF	D784037GC-xxx-3B9	80-pin plastic QFP (14 $ imes$ 14 $ imes$ 2.7 mm)	96K	3,584
★ μF	D784037GC-xxx-8BT	80-pin plastic QFP (14 $ imes$ 14 $ imes$ 1.4 mm)	96K	3,584
★ μF	D784037GK-xxx-BE9	80-pin plastic TQFP (fine pitch) (12 $ imes$ 12 mm)	96K	3,584
★ μF	D784038GC-xxx-3B9	80-pin plastic QFP (14 $ imes$ 14 $ imes$ 2.7 mm)	128K	4,352
★ μF	D784038GC-xxx-8BT	80-pin plastic QFP (14 $ imes$ 14 $ imes$ 1.4 mm)	128K	4,352
* μF	D784038GK-xxx-BE9	80-pin plastic TQFP (fine pitch) (12 $ imes$ 12 mm)	128K	4,352

Remark ××× is ROM code suffix.

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78K/IV SERIES PRODUCT DEVELOPMENT DIAGRAM



FUNCTIONS

Item		μPD784035	μPD784036	μPD784037	μPD784038		
Number of basic instructions (mnemonics)		113					
General-purpose register		8 bits \times 16 registers	$s \times 8$ banks, or 16 bits $\times 8$	registers × 8 banks (m	emory mapping)		
Minimum instructime	ction execution	125 ns/250 ns/500 ns/1,000 ns (at 32 MHz)					
Internal	ROM	48K bytes	64K bytes	96K bytes	128K bytes		
memory	RAM	2,048 bytes		3,584 bytes	4,352 bytes		
Memory space		Program and data:	1M byte				
I/O ports	Total	34					
	Input	8					
	Input/output	56					
Additional function	Pins with pull- up resistor	54					
pinsNote	LED direct drive outputs	24					
	Transistor direct drive	8					
Real-time output	it ports	4 bits \times 2, or 8 bits	× 1				
Timer/counter		Timer/counter 0: (16 bits)	Timer register \times 1 Capture register \times 1 Compare register \times 2	Pulse output c • Toggle o • PWM/PP • One-shot	utput		
		Timer/counter 1: Timer register × 1 Pulse output capability (8/16 bits) Capture register × 1 • Real-time output (4 bits × 2) Capture/compare register × 1 Compare register × 1					
		Timer/counter 2: (8/16 bits)	Timer register \times 1 Capture register \times 1 Capture/compare registe Compare register \times 1	Pulse output c • Toggle o r × 1 • PWM/PP	utput		
		Timer 3 : (8/16 bits)	Timer register \times 1 Compare register \times 1				
PWM outputs		12-bit resolution × 2 channels					
Serial interface		UART/IOE (3-wire serial I/O) : 2 channels (incorporating baud rate generator) CSI (3-wire serial I/O, 2-wire serial I/O): 1 channel					
A/D converter		8-bit resolution × 8 channels					
D/A converter		8-bit resolution × 2 channels					
Clock output		Selected from fcLK, fcLK/2, fcLK/4, fcLK/8, or fcLK/16 (can be used as a 1-bit output port)					
Watchdog timer	•	1 channel					
Standby		HALT/STOP/IDLE mode					
Interrupt	Hardware source		xternal (sampling clock va	· //			
	Software source		KCS instruction, operand	error			
	Nonmaskable	1 internal, 1 externa					
Maskable		15 internal, 6 external					
		4-level programmable priority3 operation statuses: vectored interrupt, macro service, context switching					
Supply voltage		V _{DD} = 2.7 to 5.5 V					
Package		80-pin plastic QFP ($14 \times 14 \times 2.7 \text{ mm}$) 80-pin plastic QFP ($14 \times 14 \times 1.4 \text{ mm}$) 80-pin plastic TQFP (fine pitch) ($12 \times 12 \text{ mm}$)					

 $\label{eq:Note} \mbox{ Additional function pins are included in the I/O pins.}$

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1. DIFFERENCES BETWEEN μ PD784038 SUB-SERIES

The only difference between the μ PD784035, μ PD784036, μ PD784037, and μ PD784038 is their capacity of internal memory.

The μ PD78P4038 is produced by replacing the masked ROM in the μ PD784035, μ PD784036, μ PD784037, or μ PD784038 with 128K-byte one-time PROM or EPROM. Table 1-1 shows the differences between these products.

Product	μPD784031	μPD784035	μPD784036	μPD784037	μPD784038	μPD78P4038
Internal ROM	Unavailable	48K bytes (masked ROM)	64K bytes (masked ROM)	96K bytes (masked ROM)	128K bytes (masked ROM)	128K bytes (one-time PROM or EPROM)
Internal RAM	2,048 bytes			3,584 bytes	4,352 bytes	
Package	80-pin plastic QFP ($14 \times 14 \times 2.7 \text{ mm}$) 80-pin plastic QFP ($14 \times 14 \times 1.4 \text{ mm}$) 80-pin plastic TQFP (fine pitch) ($12 \times 12 \text{ mm}$)					80-pin ceramic WQFN (14 × 14mm)

Table 1-1. Differences between the μ PD784038 Sub-Series

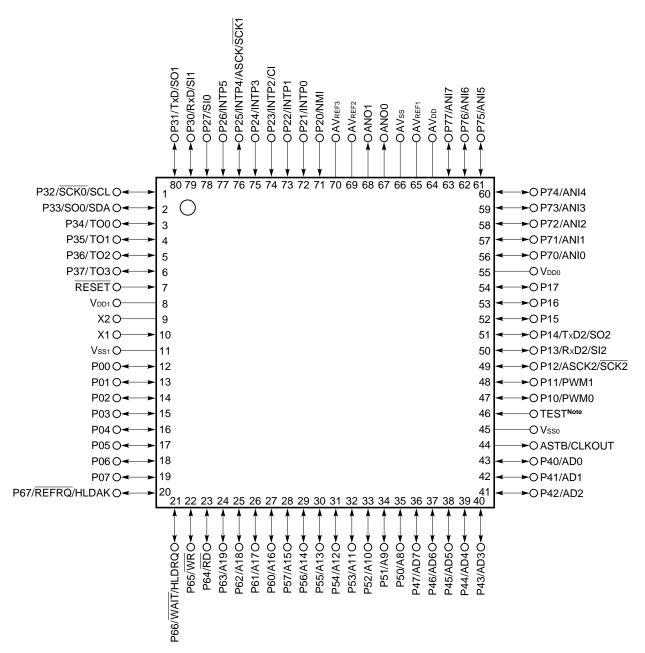
2. MAIN DIFFERENCES BETWEEN $\mu \text{PD784038}, \, \mu \text{PD784038Y}, \, \mu \text{PD784026}, \, \text{AND} \, \, \mu \text{PD78234} \, \, \text{SUBSERIES}$

Series Item		μ PD784038 sub-series μ PD784038Y sub-series	μPD784026 sub-series	μ PD78234 sub-series
Number o (mnemoni	f basic instructions ics)	113		65
Minimum time	instruction execution	125 ns (at 32 MHz)	160 ns (at 25 MHz)	333 ns (at 12 MHz)
Memory s	pace (program/data)	1M byte in total		64K bytes/1M byte
Timer/cou	nter	16-bit timer/counter × 1 8/16-bit timer/counter × 2 8/16-bit timer × 1		16-bit timer/counter × 1 8-bit timer/counter × 2 8-bit timer × 1
Clock out	put function	Available		Unavailable
Watchdog	ı timer	Available		Unavailable
Serial interface		UART/IOE (3-wire serial I/O) × 2 channels CSI (3-wire serial I/O, 2-wire serial I/O, I ² C bus ^{Note}) × 1 channel	UART/IOE (3-wire serial I/O) × 2 channels CSI (3-wire serial I/O, SBI) × 1 channel	UART × 1 channel CSI (3-wire serial I/O, SBI) × 1 channel
Interrupt	Context switching	Available	Unavailable	
	Priority	4 levels	2 levels	
Standby f	unction	3 modes (HALT, STOP, IDLE)	2 modes (HALT, STOP)	
Operation	clock switching	Selectable from fxx/2, fxx/4, fx	Fixed to fxx/2	
Pin functions	MODE pin	Unavailable		To specify ROM-less mode (always in the high level for the μ PD78233 or μ PD78237)
TEST pin		Pin for testing the device Low level during ordinary use		Unavailable
Package		80-pin plastic QFP (14 \times 14 \times 2.7 mm) 80-pin plastic QFP (14 \times 14 \times 1.4 mm) 80-pin plastic TQFP (fine pitch) (12 \times 12 mm) 80-pin ceramic WQFN (14 \times 14 mm): for the μ PD78P4038 and μ PD78P4038Y only	80-pin plastic QFP (14 \times 14 \times 2.7 mm) 80-pin plastic TQFP (fine pitch) (12 \times 12 mm): for the μ PD784021 only 80-pin ceramic WQFN (14 \times 14 mm): for the μ PD78P4026 only	80-pin plastic QFP (14 × 14 × 2.7 mm) 94-pin plastic QFP (20 × 20 mm) 84-pin plastic QFJ (1,150 ×1,150 mil) 94-pin ceramic WQFN (20 × 20 mm): for the μ PD78P238 only

Note For the μ PD784038Y sub-series only.

3. PIN CONFIGURATION (TOP VIEW)

- 80-pin plastic QFP (14 × 14 × 2.7 mm) μPD784035GC-×××-3B9, μPD784036GC-×××-3B9, μPD784037GC-×××-3B9, μPD784038GC-×××-3B9
- 80-pin plastic QFP (14 × 14 × 1.4 mm) μPD784035GC-xxx-8BT, μPD784036GC-xxx-8BT, μPD784037GC-xxx-8BT, μPD784038GC-xxx-8BT
- 80-pin plastic TQFP (fine pitch) (12 × 12 mm) μPD784035GK-×××-BE9, μPD784036GK-×××-BE9, μPD784037GK-×××-BE9, μPD784038GK-×××-BE9

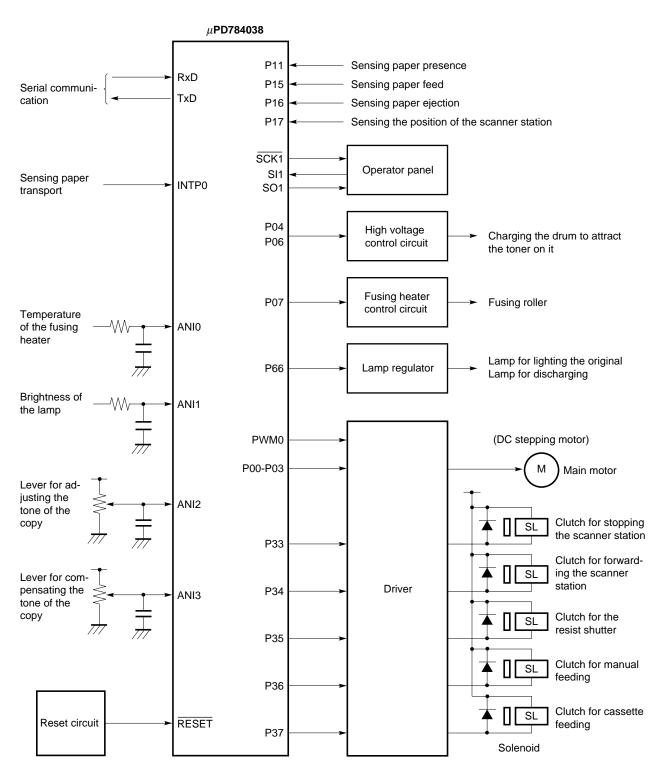


Note Connect the TEST pin to the Vsso pin directly.

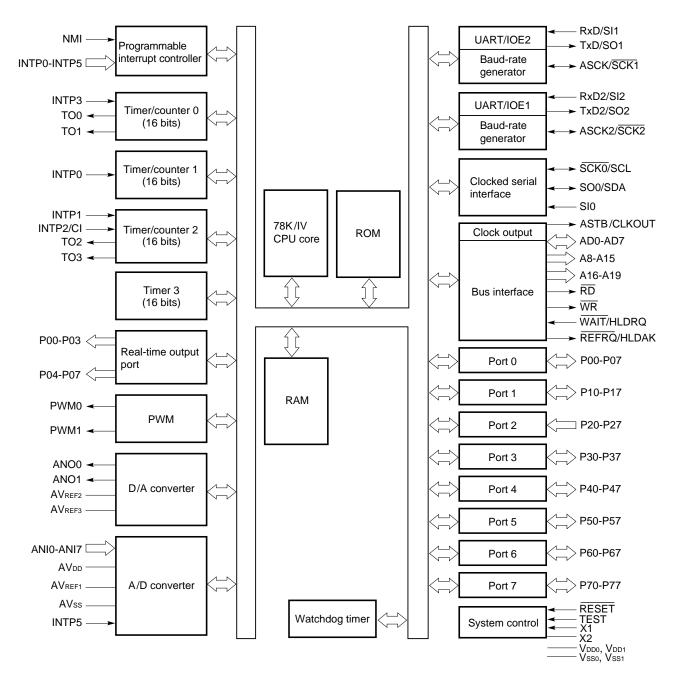
NEC

A8-A19 :	Address bus	P60-P67	: Port 6
AD0-AD7 :	Address/data bus	P70-P77	: Port 7
ANIO-ANI7 :	Analog input	PWM0, PWM1	: Pulse width modulation output
ANO0, ANO1 :	Analog output	RD	: Read strobe
ASCK, ASCK2 :	Asynchronous serial clock	REFRQ	: Refresh request
ASTB :	Address strobe	RESET	: Reset
AVDD :	Analog power supply	RxD, RxD2	: Receive data
AVREF1-AVREF3 :	Reference voltage	SCK0-SCK2	: Serial clock
AVss :	Analog ground	SCL	: Serial clock
CI :	Clock input	SDA	: Serial data
CLKOUT :	Clock output	SI0-SI2	: Serial input
HLDAK :	Hold acknowledge	SO0-SO2	: Serial output
HLDRQ :	Hold request	TEST	: Test
INTP0-INTP5 :	Interrupt from peripherals	TO0-TO3	: Timer output
NMI :	Non-maskable interrupt	TxD, TxD2	: Transmit data
P00-P07 :	Port 0	Vdd0, Vdd1	: Power supply
P10-P17 :	Port 1	Vsso, Vss1	: Ground
P20-P27 :	Port 2	WAIT	: Wait
P30-P37 :	Port 3	WR	: Write strobe
P40-P47 :	Port 4	X1, X2	: Crystal
P50-P57 :	Port 5		

4. SYSTEM CONFIGURATION EXAMPLE (PPC)



5. BLOCK DIAGRAM



Remark The internal ROM or RAM capacity differs for each product.

6. PIN FUNCTIONS

6.1 Port Pins (1/2)

Pin	I/O	Dual-function	Function
P00-P07	I/O	-	Port 0 (P0):
			• 8-bit I/O port.
			• Functions as a real-time output port (4 bits × 2).
			 Inputs and outputs can be specified bit by bit.
			• The use of the pull-up resistors can be specified by software for the pins in the input mode together.
			Can drive a transistor.
P10	I/O	PWM0	Port 1 (P1):
P11		PWM1	• 8-bit I/O port.
P12		ASCK2/SCK2	 Inputs and outputs can be specified bit by bit.
P13		RxD2/SI2	• The use of the pull-up resistors can be specified by software for the pins
P14		TxD2/SO2	in the input mode together.
P15-P17		-	Can drive LED.
P20	Input	NMI	Port 2 (P2):
P21		INTP0	8-bit input-only port.
P22		INTP1	P20 does not function as a general-purpose port (nonmaskable inter-
P23		INTP2/CI	rupt). However, the input level can be checked by an interrupt service
P24		INTP3	routine.
P25		INTP4/ASCK/SCK1	 The use of the pull-up resistors can be specified by software for pins P22 to P27 (in units of 6 bits).
P26		INTP5	• The P25/INTP4/ASCK/SCK1 pin functions as the SCK1 output pin by
P27		SIO	CSIM1.
P30	I/O	RxD/SI1	Port 3 (P3):
P31		TxD/SO1	• 8-bit I/O port.
P32		SCK0/SCL	 Inputs and outputs can be specified bit by bit.
P33		SO0/SDA	• The use of the pull-up resistors can be specified by software for the pins
P34-P37		ТО0-ТО3	in the input mode together.
P40-P47	I/O	AD0-AD7	Port 4 (P4):
			• 8-bit I/O port.
			 Inputs and outputs can be specified bit by bit.
			• The use of the pull-up resistors can be specified by software for the pins in the input mode together.
			Can drive LED.
P50-P57	I/O	A8-A15	Port 5 (P5):
			8-bit I/O port.
			 Inputs and outputs can be specified bit by bit.
			• The use of the pull-up resistors can be specified by software for the pins in the input mode together.
			Can drive LED.

6.1 Port Pins (2/2)

Pin	I/O	Dual-function	Function
P60-P63	I/O	A16-A19	Port 6 (P6):
P64		RD	• 8-bit I/O port.
P65		WR	 Inputs and outputs can be specified bit by bit.
P66		WAIT/HLDRQ	• The use of the pull-up resistors can be specified by software for the pins
P67		REFRQ/HLDAK	in the input mode together.
P70-P77	I/O	ANIO-ANI7	Port 7 (P7):
			• 8-bit I/O port.
			 Inputs and outputs can be specified bit by bit.

6.2 Non-Port Pins (1/2)

Pin	I/O	Dual-function		Function		
тоо-тоз	Output	P34-P37	Timer output	Timer output		
CI	Input	P23/INTP2	Input of a count clock	Input of a count clock for timer/counter 2		
RxD	Input	P30/SI1	Serial data input (UA	RT0)		
RxD2		P13/SI2	Serial data input (UA	RT2)		
TxD	Output	P31/SO1	Serial data output (UART0)			
TxD2		P14/SO2	Serial data output (U	ART2)		
ASCK	Input	P25/INTP4/SCK1	Baud rate clock input	(UART0)		
ASCK2		P12/SCK2	Baud rate clock input	(UART2)		
SDA	I/O	P33/SO0	Serial data I/O (2-wire	e serial I/O)		
SI0	Input	P27	Serial data input (3-w	vire serial I/O0)		
SI1		P30/RxD	Serial data input (3-w	vire serial I/O1)		
SI2		P13/RxD2	Serial data input (3-w	vire serial I/O2)		
SO0	Output	P33/SDA	Serial data output (3-	wire serial I/O0)		
SO1		P31/TxD	Serial data output (3-	wire serial I/O1)		
SO2		P14/TxD2	Serial data output (3-	wire serial I/O2)		
SCK0	I/O	P32/SCL	Serial clock I/O (3-wit	re serial I/O0)		
SCK1		P25/INTP4/ASCK	Serial clock I/O (3-with	re serial I/O1)		
SCK2		P12/ASCK2	Serial clock I/O (3-with	re serial I/O2)		
SCL		P32/SCK0	Serial clock I/O (2-wi	re serial I/O)		
NMI	Input	P20	External interrupt request	-		
INTP0		P21		 Input of a count clock for timer/counter 1 Capture/trigger signal for CR11 or CR12 		
INTP1		P22		 Input of a count clock for timer/counter 2 Capture/trigger signal for CR22 		
INTP2		P23/CI		 Input of a count clock for timer/counter 2 Capture/trigger signal for CR21 		
INTP3		P24		 Input of a count clock for timer/counter 0 Capture/trigger signal for CR02 		
INTP4		P25/ASCK/SCK1		-		
INTP5		P26	_	Input of a conversion start trigger for A/D converter		
AD0-AD7	I/O	P40-P47	Time multiplexing add	dress/data bus (for connecting external memory)		
A8-A15	Output	P50-P57	High-order address b	us (for connecting external memory)		
A16-A19	Output	P60-P63	High-order address bus of	during address expansion (for connecting external memory)		
RD	Output	P64	Strobe signal output f	for reading the contents of external memory		
WR	Output	P65	Strobe signal output for writing on external memory			
WAIT	Input	P66/HLDRQ	Wait signal insertion			
REFRQ	Output	P67/HLDAK		Refresh pulse output to external pseudo static memory		
HLDRQ	Input	P66/WAIT		Input of bus hold request		
HLDAK	Output	P67/REFRQ	Output of bus hold response			
		1	Latch timing output of time multiplexing address (A0-A7) (for connecting external memory)			
ASTB	Output	CLKOUT				

6.2 Non-Port Pins (2/2)

Pin	I/O	Dual-function	Function
RESET	Input	-	Chip reset
X1	Input	-	Crystal input for system clock oscillation (A clock pulse can also be
X2	-		input to the X1 pin.)
ANI0-ANI7	Input	P70-P77	Analog voltage inputs for the A/D converter
ANO0, ANO1	Output	-	Analog voltage inputs for the D/A converter
AV _{REF1}	-	-	Application of A/D converter reference voltage
AVREF2, AVREF3			Application of D/A converter reference voltage
AVdd			Positive power supply for the A/D converter
AVss			Ground for the A/D converter
V _{DD0} Note 1			Positive power supply of the port part
V _{DD1} Note 1			Positive power supply except for the port part
V _{SS0} Note 2			Ground of the port part
V _{SS1} Note 2			Ground except for the port part
TEST			Directly connect to the V_{SS} pin. (The TEST pin is for the IC test.)

Notes 1. The potential of the V_{DD0} pin must be equal to that of the V_{DD1} pin.

2. The potential of the Vsso pin must be equal to that of the Vss1 pin.

6.3 I/O Circuits for Pins and Handling of Unused Pins

Table 6-1 describes the types of I/O circuits for pins and the handling of unused pins. Figure 6-1 shows the configuration of these various types of I/O circuits.

Table 6-1. Types of I/O Circuits for Pins and Handling of Unused Pins (1/2)

Pin	I/O circuit type	I/O	Recommended connection method for unused pins
P00-P07	5-H	I/O	Input state : Connect these pins to the VDD0 pin.
P10/PWM0			Output state: Leave open.
P11/PWM1			
P12/ASCK2/SCK2	8-C		
P13/RxD2/SI2	5-H		
P14/TxD2/SO2			
P15-P17			
P20/NMI	2	Input	Connect these pins to the VDD0 or VSS0 pin.
P21/INTP0			
P22/INTP1	2-C		Connect these pins to the VDD0 pin.
P23/INTP2/CI			
P24/INTP3			
P25/INTP4/ASCK/SCK1	8-C	I/O	Input state : Connect this pin to the VDD0 pin.
			Output state: Leave open.
P26/INTP5	2-C	Input	Connect these pins to the VDD0 pin.
P27/SI0			
P30/RxD/SI1	5-H	I/O	Input state $:$ Connect these pins to the VDD0 pin.
P31/TxD/SO1			Output state: Leave open.
P32/SCK0/SCL	10-B		
P33/SO0/SDA			
P34/TO0-P37/TO3	5-H		
P40/AD0-P47/AD7			
P50/A8-P57/A15			
P60/A16-P63/A19			
P64/RD			
P65/WR			
P66/WAIT/HLDRQ			
P67/REFRQ/HLDAK			
P70/ANI0-P77/ANI7	20-A	I/O	Input state : Connect this pin to the VDD0 or VSS0 pin.
			Output state: Leave open.
ANO0, ANO1	12	Output	Leave open.
ASTB/CLKOUT	4-B		

Table 6-1. Types of I/O Circuits for Pins and Handling of Unused Pins (2/2)

Pin	I/O circuit type	I/O	Recommended connection method for unused pins
RESET	2	Input	-
TEST	1-A		Connect this pin to the Vsso pin directly.
AVREF1-AVREF3	-		Connect these pins to the Vsso pin.
AVss			
AVDD			Connect this pin to the VDD0 pin.

- Caution When the I/O mode of an I/O dual-function pin is unpredictable, connect the pin to VDD0 through a resistor of 10 to 100 kilohms (particularly when the voltage of the reset input pin becomes higher than that of the low-level input at power-on or when I/O is switched by software).
- **Remark** Since type numbers are consistent in the 78K series, those numbers are not always serial in each product. (Some circuits are not included.)

Type 1-A Type 2-C Vdd0 1 VDD0 ►P ا ج $IN \bigcirc$ Pull-up P◄ enable ←N /// Vsso $IN \bigcirc$ Type 2 Schmitt trigger input with hysteresis characteristics INOType 5-H Vdd0 Schmitt trigger input with hysteresis characteristics ↓ ↓ ↓ ↓ ₽ Type 4-B Vdd0 Pull-up Þ enable VDD0 Data ► P Data ₽ OUT Ž Output disable Output disable ←N - N 7∕/7Vs 7/7 Vsso Input enable Push-pull output which can output high impedance (both the positive and negative channels are off.) Type 8-C Type 12 Vdd0 + ∮€₽ Pull-up enable Vdd0 Data ₽ Analog output voltage OUT O IN/OUT Λ Output disable ΕN /// Vsso Type 10-B Type 20-A Vdd0 V_{DD0} Data † ₹ ₹ ► D Pull-up OIN/OUT enable Δ Output **≺**-N VDD0 disable ┨<mark>┝</mark>╴Ϸ Data 7777 Vsso Comparator Open drain -l**E**-N Output disable AVREF 777 Vsso AVss (Threshold voltage) Input enable

Figure 6-1. I/O Circuits for Pins

7. CPU ARCHITECTURE

7.1 Memory Space

A 1M-byte memory space can be accessed. By using a LOCATION instruction, the mode for mapping internal data areas (special function registers and internal RAM) can be selected. A LOCATION instruction must always be executed after a reset, and can be used only once.

(1) When the LOCATION 0 instruction is executed

• Internal memory

The table below indicates the internal data areas and internal ROM areas of each product.

Product name	Internal data area	Internal ROM area
μPD784035	0F700H-0FFFFH	00000H-0BFFFH
μPD784036		00000H-0F6FFH
μPD784037	0F100H-0FFFFH	00000H-0F0FFH 10000H-17FFFH
μPD784038	0EE00H-0FFFFH	00000H-0FDFFH 10000H-1FFFFH

Caution The following internal ROM areas, existing at the same addresses as the internal data areas, cannot be used when the LOCATION 0 instruction is executed:

Product name	Unusable area
μPD784035	-
μPD784036	0F700H-0FFFFH (2,304 bytes)
μPD784037	0F100H-0FFFFH (3,840 bytes)
μPD784038	0EE00H-0FFFFH (4,608 bytes)

• External memory

External memory is accessed in external memory expansion mode.

(2) When the LOCATION 0FH instruction is executed

• Internal memory

The table below lists the internal data areas and internal ROM areas for each product.

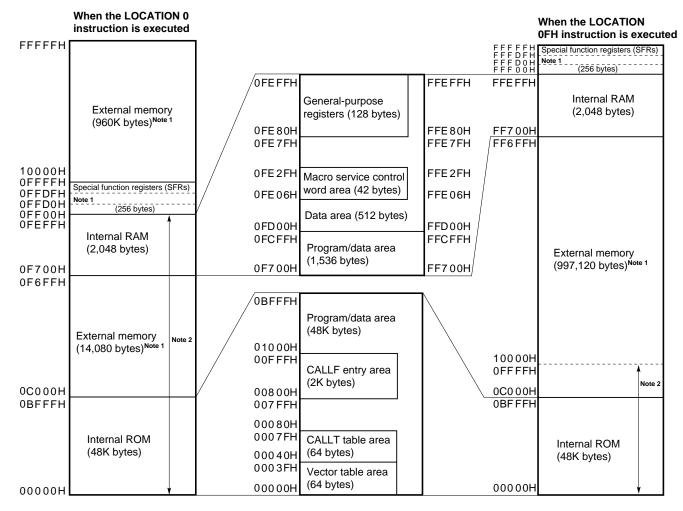
Product name	Internal data area	Internal ROM area
μPD784035	FF700H-FFFFFH	00000H-0BFFFH
μPD784036		00000H-0FFFFH
μPD784037	0F100H-FFFFFH	00000H-17FFFH
μPD784038	FEE00H-FFFFFH	00000H-1FFFFH

• External memory

External memory is accessed in external memory expansion mode.

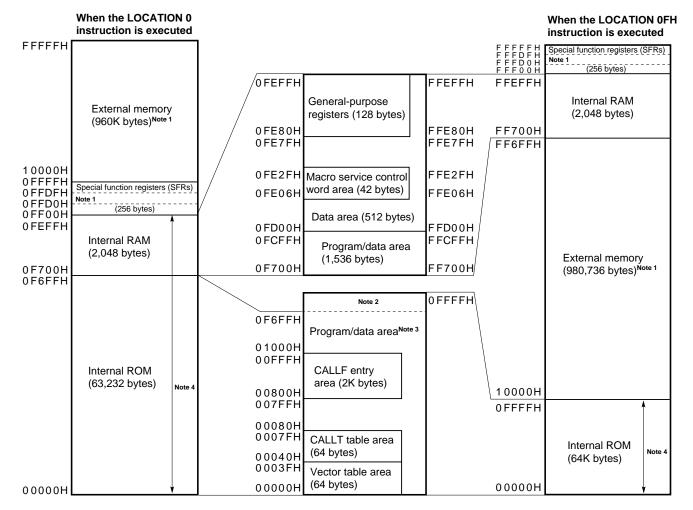
μ PD784035, 784036, 784037, 784038

Figure 7-1. µPD784035 Memory Map



Notes 1. Accessed in external memory expansion mode.

2. Base area, or entry area based on a reset or interrupt. Internal RAM is excluded in the case of a reset.



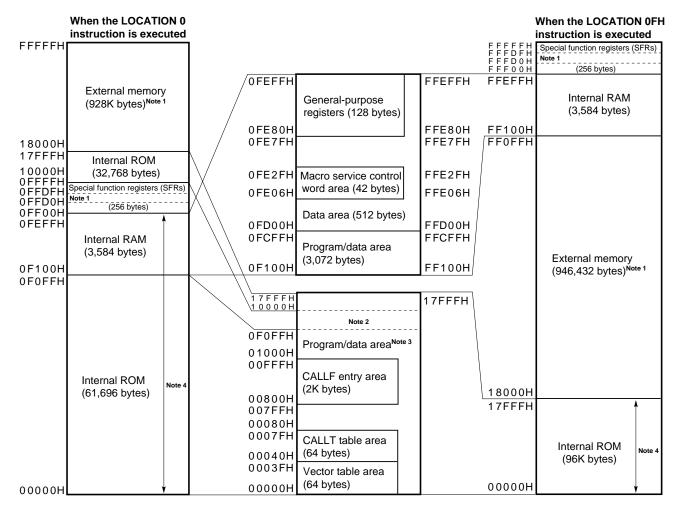
Notes 1. Accessed in external memory expansion mode.

2. This 2,304-byte area can be used as an internal ROM area only when the LOCATION 0FH instruction is executed.

3. When the LOCATION 0 instruction is executed : 63,232 bytes When the LOCATION 0FH instruction is executed: 65,536 bytes

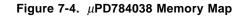
4. Base area, or entry area based on a reset or interrupt. Internal RAM is excluded in the case of a reset.

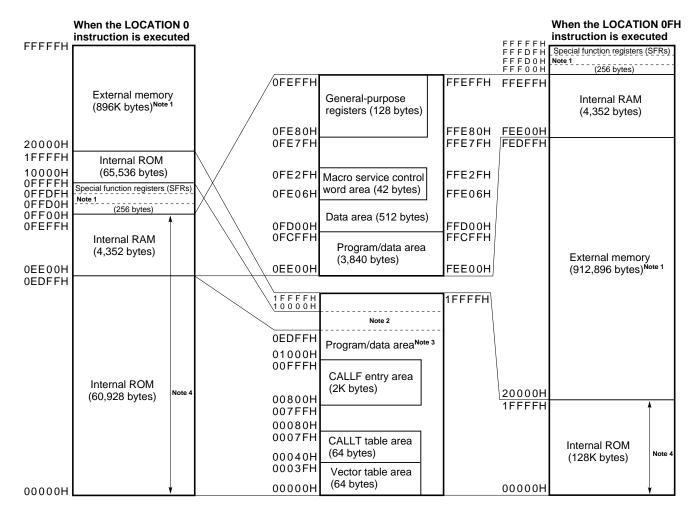
Figure 7-3. µPD784037 Memory Map



Notes 1. Accessed in external memory expansion mode.

- 2. This 3,840-byte area can be used as an internal ROM area only when the LOCATION 0FH instruction is executed.
- **3.** When the LOCATION 0 instruction is executed : 94,464 bytes When the LOCATION 0FH instruction is executed: 98,304 bytes
- 4. Base area, or entry area based on a reset or interrupt. Internal RAM is excluded in the case of a reset.





Notes 1. Accessed in external memory expansion mode.

- 2. This 4,608-byte area can be used as an internal ROM area only when the LOCATION 0FH instruction is executed.
- **3.** When the LOCATION 0 instruction is executed : 126,464 bytes When the LOCATION 0FH instruction is executed: 131,072 bytes
- 4. Base area, or entry area based on a reset or interrupt. Internal RAM is excluded in the case of a reset.

7.2 CPU Registers

7.2.1 General-purpose registers

A set of general-purpose registers consists of sixteen general-purpose 8-bit registers. Two 8-bit general-purpose registers can be combined to form a 16-bit general-purpose register. Moreover, four 16-bit general-purpose registers, when combined with an 8-bit register for address extension, can be used as 24-bit address specification registers.

Eight banks of this register set are provided. The user can switch between banks by software or the context switching function.

General-purpose registers other than the V, U, T, and W registers used for address extension are mapped onto internal RAM.

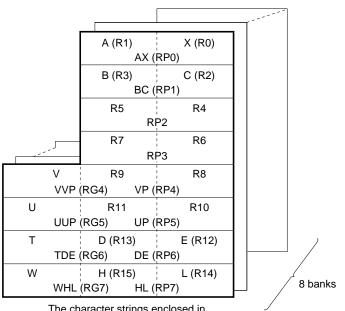


Figure 7-5. General-Purpose Register Format

The character strings enclosed in parentheses represent absolute names.

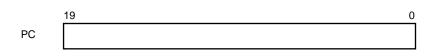
Caution By setting the RSS bit of PSW to 1, R4, R5, R6, R7, RP2, and RP3 can be used as the X, A, C, B, AX, and BC registers, respectively. However, this function must be used only when using programs for the 78K/III series.

7.2.2 Control registers

(1) Program counter (PC)

This register is a 20-bit program counter. The program counter is automatically updated by program execution.

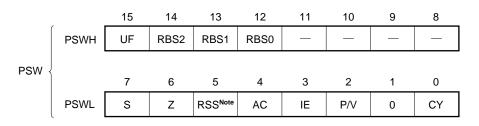
Figure 7-6. Format of Program Counter (PC)



(2) Program Status Word (PSW)

This register holds the CPU state. The program status word is automatically updated by program execution.

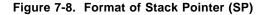
Figure 7-7. Format of Program Status Word (PSW)

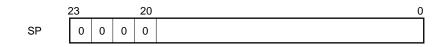


Note This flag is used to maintain compatibility with the 78K/III series. This flag must be set to 0 when programs for the 78K/III series are being used.

(3) Stack pointer (SP)

This register is a 24-bit pointer for holding the start address of the stack. The high-order 4 bits must be set to 0.





7.2.3 Special function registers (SFRs)

The special function registers are registers with special functions such as mode registers and control registers for built-in peripheral hardware. The special function registers are mapped onto the 256-byte space between 0FF00H and 0FFFFHNote.

- **Note** Applicable when the LOCATION 0 instruction is executed. FFF00H-FFFFFH when the LOCATION 0FH instruction is executed.
- Caution Never attempt to access addresses in this area where no SFR is allocated. Otherwise, the μ PD784038 may be placed in the deadlock state. The deadlock state can be cleared only by a reset.

Table 7-1 lists the special function registers (SFRs). The titles of the table columns are explained below.

- Abbreviation Symbol used to represent a built-in SFR. The abbreviations listed in the table are
 reserved words for the NEC assembler (RA78K4). The C compiler (CC78K4) allows
 the abbreviations to be used as sfr variables with the #pragma sfr command.
- R/W Indicates whether each SFR allows read and/or write operations.
 - R/W : Allows both read and write operations.
 - R : Allows read operations only.
 - W : Allows write operations only.
- Manipulatable bits Indicates the maximum number of bits that can be manipulated whenever an SFR is
 manipulated. An SFR that supports 16-bit manipulation can be described in the sfrp
 operand. For address specification, an even-numbered address must be speci fied.

An SFR that supports 1-bit manipulation can be described in a bit manipulation instruction.

• When reset Indicates the state of each register when RESET is applied.

A dalara a a Noto	Special function register (SED) serve		Abbreviation		DAV	Manipulatable bits			When react
Address Note	Special function register (SFR) na	ime	Abbre	eviation	R/W	1 bit	8 bits	16 bits	When reset
0FF00H	Port 0		P0		R/W	0	0	-	Undefined
0FF01H	Port 1					0	0	-	
0FF02H	Port 2				R	0	0	-	
0FF03H	Port 3		P3		R/W	0	0	-	
0FF04H	Port 4		P4			0	0	-	
0FF05H	Port 5		P5			0	0	-	
0FF06H	Port 6		P6			0	0	-	00H
0FF07H	Port 7		P7			0	0	-	Undefined
0FF0EH	Port 0 buffer r	egister L	P0L			0	0	-	
0FF0FH	Port 0 buffer register H		P0H			0	0	-	
0FF10H	Compare register (timer/counter 0)		CR00			-	-	0	
0FF12H	Capture/compare register (timer/counter	er 0)	CR01			-	-	0	
0FF14H	Compare register L (timer/counter 1)		CR10	CR10W		-	0	0	
0FF15H	Compare register H (timer/counter 1)		-			-	-		
0FF16H	Capture/compare register L (timer/cour	nter 1)	CR11	CR11W		-	0	0	
0FF17H	Capture/compare register H (timer/cour	nter 1)	-			-	-		
0FF18H	Compare register L (timer/counter 2)		CR20	CR20W		-	0	0	
0FF19H	Compare register H (timer/counter 2)		-			-	-	_	
0FF1AH	Capture/compare register L (timer/cour	nter 2)	CR21	CR21W		-	0	0	
0FF1BH	Capture/compare register H (timer/cour	nter 2)	-			-	-		
0FF1CH	Compare register L (timer 3)		CR30	CR30W		-	0	0	
0FF1DH	Compare register H (timer 3)		-			-	-		
0FF20H	Port 0 mode register		PM0			0	0	-	FFH
0FF21H	Port 1 mode register		PM1			0	0	-	
0FF23H	Port 3 mode register		PM3			0	0	-	
0FF24H	Port 4 mode register		PM4			0	0	-	
0FF25H	Port 5 mode register		PM5			0	0	-	
0FF26H	Port 6 mode register		PM6			0	0	-	
0FF27H	Port 7 mode register		PM7			0	0	-	
0FF2EH	Real-time output port control register		RTPC			0	0	-	00H
0FF30H	Capture/compare control register 0		CRC0			-	0	-	10H
0FF31H	Timer output control register		тос			0	0	-	00H
0FF32H	Capture/compare control register 1		CRC1			-	0	-	
0FF33H	Capture/compare control register 2		CRC2			-	0	-	10H

Table 7-1. Special Function Registers (SFRs) (1/4)

Note Applicable when the LOCATION 0 instruction is executed. When the LOCATION 0FH instruction is executed, F0000H is added to each address.

A data a Noto				DAA	Mani	pulatabl	e bits	When reset
Address Note	Special function register (SFR) name	Abbre	eviation	R/W	1 bit	8 bits	16 bits	
0FF36H	Capture register (timer/counter 0)	CR02	CR02		-	-	0	0000H
0FF38H	Capture register L (timer/counter 1)	CR12	CR12W		-	0	0	
0FF39H	Capture register H (timer/counter 1)	-			-	-		
0FF3AH	Capture register L (timer/counter 2)	CR22	CR22W		-	0	0	
0FF3BH	Capture register H (timer/counter 2)	-			I	-		
0FF41H	Port 1 mode control register	PMC1		R/W	0	0	-	00H
0FF43H	Port 3 mode control register	PMC3			0	0	-	
0FF4EH	Register for optional pull-up resistor	PUO			0	0	-	
0FF50H	Timer register 0	ТМ0		R	-	-	0	0000H
0FF51H					-	-		
0FF52H	Timer register 1	TM1	TM1W		-	0	0	
0FF53H		-			-	-		
0FF54H	Timer register 2	TM2	TM2W		-	0	0	
0FF55H		-			-	-		
0FF56H	Timer register 3	ТМЗ	тмзw		-	0	0	
0FF57H		-			-	-		
0FF5CH	Prescaler mode register 0	PRM0		R/W	-	0	-	11H
0FF5DH	Timer control register 0	тмсо			0	0	-	00H
0FF5EH	Prescaler mode register 1	PRM1			-	0	-	11H
0FF5FH	Timer control register 1	TMC1			0	0	-	00H
0FF60H	D/A conversion value setting register 0	DACS	0		-	0	-	
0FF61H	D/A conversion value setting register 1	DACS	1		-	0	-	
0FF62H	D/A converter mode register	DAM			0	0	-	03H
0FF68H	A/D converter mode register	ADM			0	0	-	00H
0FF6AH	A/D conversion result register	ADCR		R	-	0	-	Undefined
0FF70H	PWM control register	PWMC	;	R/W	0	0	-	05H
0FF71H	PWM prescaler register	PWPR			-	0	-	00H
0FF72H	PWM modulo register 0	PWM0			-	-	0	Undefined
0FF74H	PWM modulo register 1	PWM1]	-	-	0	
0FF7DH	One-shot pulse output control register	OSPC		1	0	0	-	00H
0FF80H	I ² C bus control register	IICC		1	0	0	-	
0FF81H	Prescaler mode register for serial clock	SPRM		1	-	0	-	04H
0FF82H	Synchronous serial interface mode register	CSIM			0	0	-	00H

Note Applicable when the LOCATION 0 instruction is executed. When the LOCATION 0FH instruction is executed, F0000H is added to each address.

A data a sNoto 1	Special function register (SED) nome	Abbrevietien	R/W	Manipulatable bits			When reset
AddressNote 1	Special function register (SFR) name	Abbreviation	R/W	1 bit	8 bits	16 bits	When leset
0FF84H	Synchronous serial interface mode register 1	CSIM1	R/W	0	0	-	00H
0FF85H	Synchronous serial interface mode register 2	CSIM2	1	0	0	-	
0FF86H	Serial shift register	SIO	1	-	0	-	
0FF88H	Asynchronous serial interface mode register	ASIM]	0	0	-	
0FF89H	Asynchronous serial interface mode register 2	ASIM2]	0	0	-	
0FF8AH	Asynchronous serial interface status register	ASIS	R	0	0	-	
0FF8BH	Asynchronous serial interface status register 2	ASIS2	1	0	0	-	
0FF8CH	Serial receive buffer: UART0	RXB]	-	0	-	Undefined
	Serial transmission shift register: UART0	TXS	W	-	0	-	
	Serial shift register: IOE1	SIO1	R/W	-	0	-	
0FF8DH	Serial receive buffer: UART2	RXB2	R	-	0	-	
	Serial transmission shift register: UART2	TXS2	W	-	0	-	
	Serial shift register: IOE2	SIO2	R/W	-	0	-	
0FF90H	Baud rate generator control register	BRGC	1	-	0	-	00H
0FF91H	Baud rate generator control register 2	BRGC2	1	-	0	-	
0FFA0H	External interrupt mode register 0	INTM0	1	0	0	-	
0FFA1H	External interrupt mode register 1	INTM1	1	0	0	-	
0FFA4H	Sampling clock selection register	SCS0	1	-	0	-	
0FFA8H	In-service priority register	ISPR	R	0	0	-	
0FFAAH	Interrupt mode control register	IMC	R/W	0	0	-	80H
0FFACH	Interrupt mask register 0L	MKOL MKO	1	0	0	0	FFFFH
0FFADH	Interrupt mask register 0H	мкон		0	0		
0FFAEH	Interrupt mask register 1L	MK1L	1	0	0	-	FFH
0FFC0H	Standby control register	STBC		-	ONote 2	-	30H
0FFC2H	Watchdog timer mode register	WDM	1	-	ONote 2	-	00H
0FFC4H	Memory expansion mode register	ММ	1	0	0	-	20H
0FFC5H	Hold mode register	HLDM]	0	0	-	00H
0FFC6H	Clock output mode register	CLOM	1	0	0	-	
0FFC7H	Programmable wait control register 1	PWC1	1	-	0	-	AAH
0FFC8H	Programmable wait control register 2	PWC2		-	-	0	AAAAH

- **Notes 1.** Applicable when the LOCATION 0 instruction is executed. When the LOCATION 0FH instruction is executed, F0000H is added to each address.
 - **2.** A write operation can be performed only with special instructions MOV STBC,#byte and MOV WDM,#byte. Other instructions cannot perform a write operation.

AddressNote	Special function register (SFR) name	Abbroviation	R/W	Manipulatable bits			When reset
Addressive	Special function register (SFR) hame	Abbreviation		1 bit	8 bits	16 bits	when reset
0FFCCH	Refresh mode register	RFM	R/W	0	0	-	00H
0FFCDH	Refresh area specification register	RFA		0	0	-	
0FFCFH	Oscillation settling time specification register	OSTS		-	0	-	
0FFD0H-	External SFR area	-		0	0	-	-
0FFDFH							
0FFE0H	Interrupt control register (INTP0)	PIC0		0	0	-	43H
0FFE1H	Interrupt control register (INTP1)	PIC1		0	0	-	
0FFE2H	Interrupt control register (INTP2)	PIC2		0	0	-	
0FFE3H	Interrupt control register (INTP3)	PIC3		0	0	-	
0FFE4H	Interrupt control register (INTC00)	CIC00		0	0	-	
0FFE5H	Interrupt control register (INTC01)	CIC01		0	0	-	
0FFE6H	Interrupt control register (INTC10)	CIC10		0	0	-	
0FFE7H	Interrupt control register (INTC11)	CIC11		0	0	-	
0FFE8H	Interrupt control register (INTC20)	CIC20		0	0	-	
0FFE9H	Interrupt control register (INTC21)	CIC21		0	0	-	
0FFEAH	Interrupt control register (INTC30)	CIC30		0	0	-	
0FFEBH	Interrupt control register (INTP4)	PIC4		0	0	-	
0FFECH	Interrupt control register (INTP5)	PIC5		0	0	-	
0FFEDH	Interrupt control register (INTAD)	ADIC		0	0	-	
OFFEEH	Interrupt control register (INTSER)	SERIC		0	0	-	
0FFEFH	Interrupt control register (INTSR)	SRIC		0	0	-	
	Interrupt control register (INTCSI1)	CSIIC1		0	0	-	
0FFF0H	Interrupt control register (INTST)	STIC		0	0	-	
0FFF1H	Interrupt control register (INTCSI)	CSIIC		0	0	-	
0FFF2H	Interrupt control register (INTSER2)	SERIC2		0	0	-	
0FFF3H	Interrupt control register (INTSR2)	SRIC2		0	0	-	
	Interrupt control register (INTCSI2)	CSIIC2		0	0	-	
0FFF4H	Interrupt control register (INTST2)	STIC2		0	0	-	

Table 7-1. Special Function Registers (SFRs) (4/4)

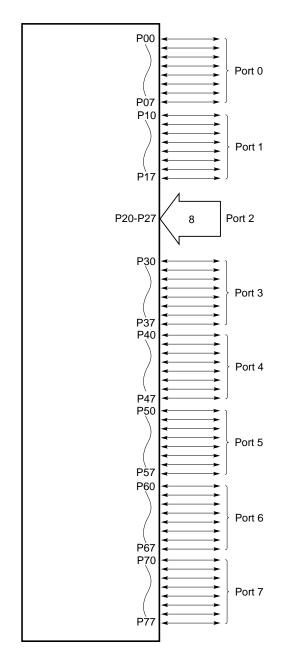
Note Applicable when the LOCATION 0 instruction is executed. When the LOCATION 0FH instruction is executed, F0000H is added to each address.

8. PERIPHERAL HARDWARE FUNCTIONS

8.1 Ports

The ports shown in Figure 8-1 are provided to enable the application of wide-ranging control. Table 8-1 lists the functions of the ports. For the inputs to port 0 to port 6, a built-in pull-up resistor can be specified by software.



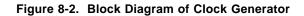


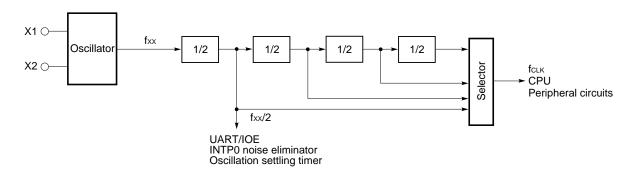
Port name	Pin	Function	Pull-up specification by software
Port 0	P00-P07	 Bit-by-bit input/output setting supported Operable as 4-bit real-time outputs (P00-P03, P04-P07) Capable of driving transistors 	Specified as a batch for all pins placed in input mode.
Port 1	P10-P17	Bit-by-bit input/output setting supportedCapable of driving LEDs	Specified as a batch for all pins placed in input mode.
Port 2	P20-P27	Input port	Specified for the 6 bits (P22-P27) as a batch.
Port 3	P30-P37	Bit-by-bit input/output setting supported	Specified as a batch for all pins placed in input mode.
Port 4	P40-P47	Bit-by-bit input/output setting supportedCapable of driving LEDs	Specified as a batch for all pins placed in input mode.
Port 5	P50-P57	Bit-by-bit input/output setting supportedCapable of driving LEDs	Specified as a batch for all pins placed in input mode.
Port 6	P60-P67	Bit-by-bit input/output setting supported	Specified as a batch for all pins placed in input mode.
Port 7	P70-P77	Bit-by-bit input/output setting supported	-

Table 8-1. Port Functions

8.2 Clock Generator

A circuit for generating the clock signal required for operation is provided. The clock generator includes a frequency divider; low current consumption can be achieved by operating at a lower internal frequency when high-speed operation is not necessary.

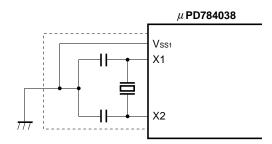




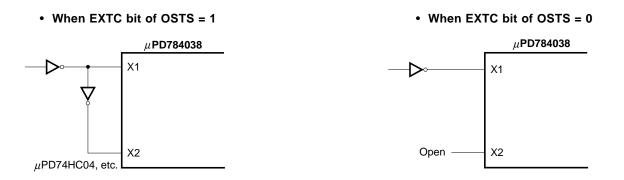
Remark fxx : Oscillator frequency or external clock input frequency fcLk: Internal operating frequency

Figure 8-3. Examples of Using Oscillator

(1) Crystal/ceramic oscillation



(2) External clock



- Caution When using the system clock generator, run wires in the portion surrounded by broken lines according to the following rules to avoid effects such as stray capacitance:
 - Minimize the wiring.
 - Never cause the wires to cross other signal lines.
 - Never cause the wires to run near a line carrying a large varying current.
 - Cause the grounding point of the capacitor of the oscillator circuit to have the same potential as Vss1. Never connect the capacitor to a ground pattern carrying a large current.
 - Never extract a signal from the oscillator.

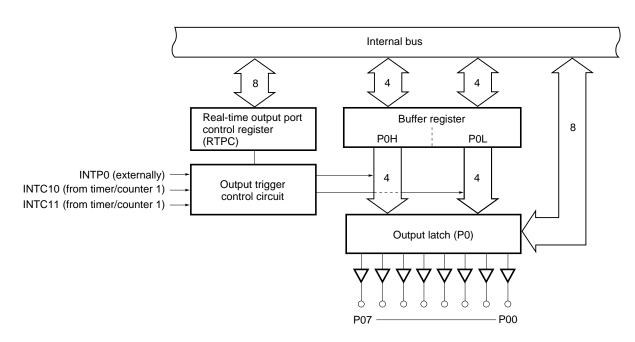
8.3 Real-Time Output Port

The real-time output port outputs data stored in the buffer, synchronized with a timer/counter 1 match interrupt or external interrupt. Thus, pulse output that is free of jitter can be obtained.

Therefore, the real-time output port is best suited to applications (such as open-loop control over stepping motors) where an arbitrary pattern is output at arbitrary intervals.

As shown in Figure 8-4, the real-time output port is built around port 0 and the port 0 buffer register (P0H, P0L).

Figure 8-4. Block Diagram of Real-Time Output Port



8.4 Timers/Counters

Three timer/counter units and one timer unit are incorporated.

Moreover, seven interrupt requests are supported, allowing these units to function as seven timer/counter units.

ltem		Name	Timer/counter 0	Timer/counter 1	Timer/counter 2	Timer 3
Count pulse width	8 bits		-	0	0	0
	16 bits		0	0	0	0
Operating mode	Interval timer		2ch	2ch	2ch	1ch
	External event counter		0	0	0	-
	One-shot timer		-	-	0	-
Function	Tin	ner output	2ch	-	2ch	-
		Toggle output	0	-	0	-
		PWM/PPG output	0	-	0	-
	One-shot pulse outpu		0	-	-	-
	Re	al-time output	-	0	-	-
	Pulse width measurement		1 input	1 input	2 inputs	-
	Nu	mber of interrupt requests	2	2	2	1

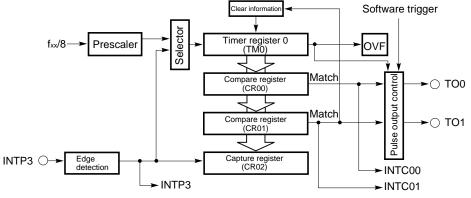
Table 8-2. Timer/Counter Operation

Note The one-shot pulse output function makes the level of a pulse output active by software, and makes the level of a pulse output inactive by hardware (interrupt request signal).

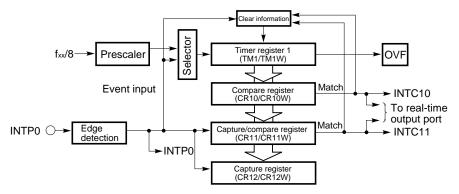
Note that this function differs from the one-shot timer function of timer/counter 2.

Figure 8-5. Timer/Counter Block Diagram

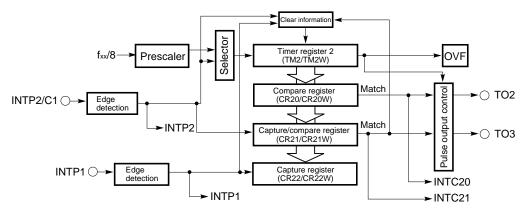
Timer/counter 0



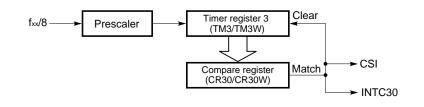
Timer/counter 1

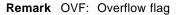


Timer/counter 2



Timer 3





8.5 PWM Output (PWM0, PWM1)

Two channels of PWM (pulse width modulation) output circuitry with a resolution of 12 bits and a repetition frequency of 62.5 kHz (fclk = 16 MHz) are incorporated. Low or high active level can be selected for the PWM output channels, independently of each other. This output is best suited to DC motor speed control.

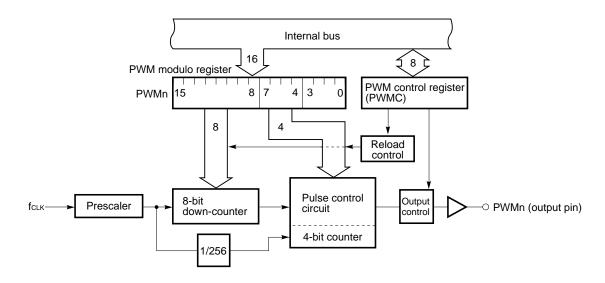


Figure 8-6. Block Diagram of PWM Output Unit

Remark n = 0, 1

8.6 A/D Converter

An analog/digital (A/D) converter having 8 multiplexed analog inputs (ANI0-ANI7) is incorporated.

The successive approximation system is used for conversion. The result of conversion is held in the 8-bit A/D conversion result register (ADCR). Thus, speedy high-precision conversion can be achieved. (The conversion time is about 7.5 μ s at fcLk = 16 MHz.)

A/D conversion can be started in any of the following modes:

- Hardware start: Conversion is started by means of trigger input (INTP5).
- Software start : Conversion is started by means of bit setting the A/D converter mode register (ADM).

After conversion has started, one of the following modes can be selected:

- Scan mode : Multiple analog inputs are selected sequentially to obtain conversion data from all pins.
- Select mode: A single analog input is selected at all times to enable conversion data to be obtained continuously.

ADM is used to specify the above modes, as well as the termination of conversion.

When the result of conversion is transferred to ADCR, an interrupt request (INTAD) is generated. Using this feature, the results of conversion can be continuously transferred to memory by the macro service.

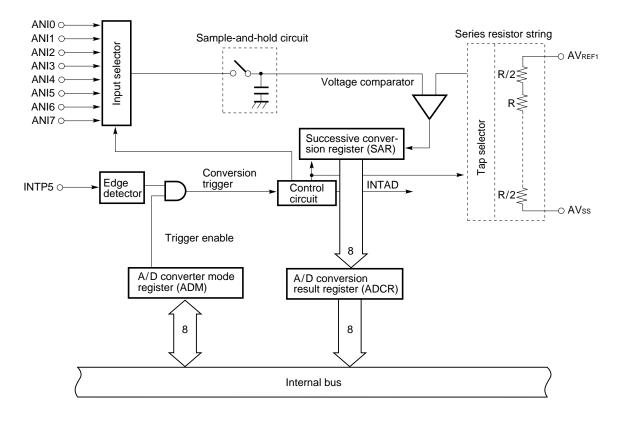


Figure 8-7. Block Diagram of A/D Converter

8.7 D/A Converter

Two digital/analog (D/A) converter channels of voltage output type, having a resolution of 8 bits, are incorporated. An R-2R resistor ladder system is used for conversion. By writing the value to be subject to D/A conversion in the 8-bit D/A conversion value setting register (DACSn: n = 0, 1), the resulting analog value is output on ANOn (n = 0, 1). The range of the output voltages is determined by the voltages applied to the AV_{REF2} and AV_{REF3} pins. Because of its high output impedance, no current can be obtained from an output pin. When the load impedance is low, insert a buffer amplifier between the load and the converter.

The impedance of the ANOn pin goes high while the $\overline{\text{RESET}}$ signal is low. DACSn is set to 0 after a reset is released.

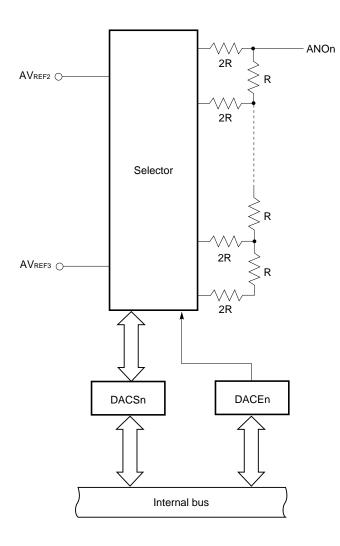


Figure 8-8. Block Diagram of D/A Converter

Remark n = 0, 1

8.8 Serial Interface

Three independent serial interface channels are incorporated.

- Asynchronous serial interface (UART)/three-wire serial I/O (IOE) $\times\,2$
- Synchronous serial interface (CSI) $\times\,1$
 - Three-wire serial I/O (IOE)
 - Two-wire serial I/O (IOE)

So, communication with points external to the system and local communication within the system can be performed at the same time. (See **Figure 8-9**.)

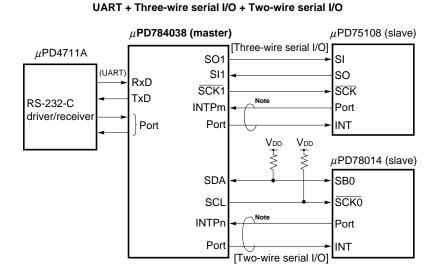


Figure 8-9. Example Serial Interfaces

Note Handshake line

8.8.1 Asynchronous serial interface/three-wire serial I/O (UART/IOE)

Two serial interface channels are available; for each channel, asynchronous serial interface mode or three-wire serial I/O mode can be selected.

(1) Asynchronous serial interface mode

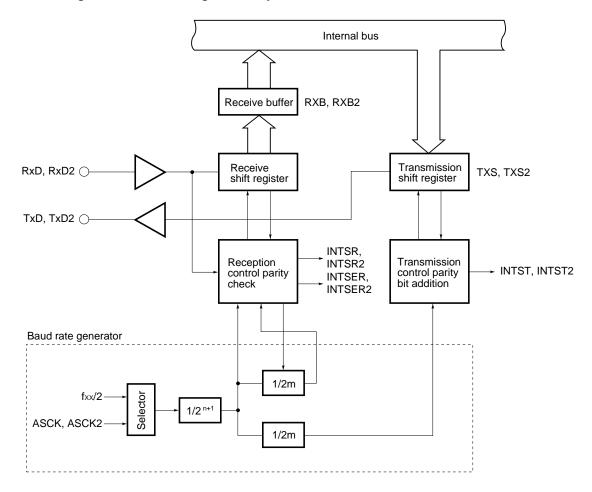
In this mode, 1-byte data is transferred after a start bit.

A baud rate generator is incorporated to enable communication at a wide range of baud rates.

Moreover, the frequency of a clock signal applied to the ASCK pin can be divided to define a baud rate.

With the baud rate generator, the baud rate conforming to the MIDI standard (31.25 kbps) can be obtained.

Figure 8-10. Block Diagram of Asynchronous Serial Interface Mode



Remark fxx: Oscillator frequency or external clock input frequency

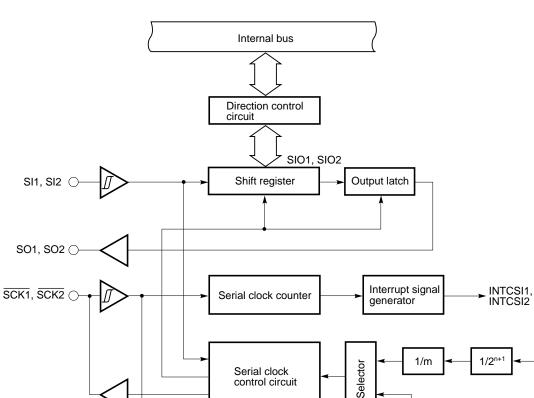
n = 0 to 11 m = 16 to 30

(2) Three-wire serial I/O mode

In this mode, the master device makes the serial clock active to start transmission, then transfers 1-byte data in phase with the clock.

This mode is designed for communication with a device incorporating a conventional synchronous serial interface. Basically, three lines are used for communication: the serial clock line (SCK) and the two serial data lines (SI and SO).

In general, a handshake line is required to check the communication state.



Serial clock control circuit

Figure 8-11. Block Diagram of Three-Wire Serial I/O Mode

Remark fxx: Oscillator frequency or external clock input frequency

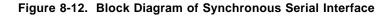
n = 0 to 11

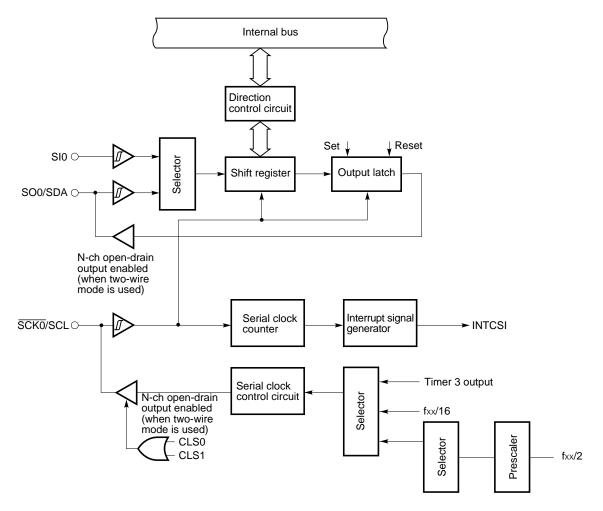
m = 1, 16 to 30

fxx/2

8.8.2 Synchronous serial interface (CSI)

With this interface, the master device makes the serial clock active to start transmission, then transfers 1-byte data in phase with the clock.





Remark fxx: Oscillator frequency or external clock input frequency

(1) Three-wire serial I/O mode

This mode is designed for communication with a device incorporating a conventional synchronous serial interface. Basically, three lines are used for communication: the serial clock line ($\overline{SCK0}$) and serial data lines (SI0 and SO0). In general, a handshake line is required to check the communication state.

(2) Two-wire serial I/O mode

In this mode, 8-bit data is transferred using two lines: the serial clock line (SCL) and serial data bus (SDA). In general, a handshake line is required to check the communication state.

8.9 Clock Output Function

The frequency of the CPU clock signal can be divided for output to a point external to the system. Moreover, the port can be used as a 1-bit port.

The ASTB pin is also used for the CLKOUT pin, so that when this function is used, the local bus interface cannot be used.

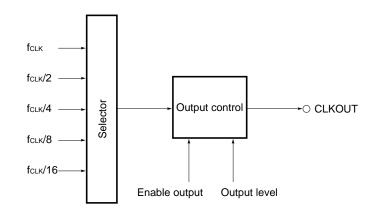


Figure 8-13. Block Diagram of Clock Output Function

8.10 Edge Detection Function

The interrupt input pins (NMI, INTPO-INTP5) are used to apply not only interrupt requests but also trigger signals for the built-in circuits. As these pins are triggered by an edge (rising or falling) of an input signal, a function for edge detection is incorporated. Moreover, a noise suppression function is provided to prevent erroneous edge detection caused by noise.

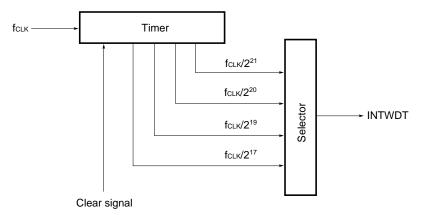
Pin	Detectable edge	Noise suppression method
NMI	Rising edge or falling edge	Analog delay
INTP0-INTP3	Rising edge or falling edge, or both edges	Clock samplingNote
INTP4, INTP5		Analog delay

Note INTP0 is used for sampling clock selection.

8.11 Watchdog Timer

A watchdog timer is incorporated for CPU runaway detection. The watchdog timer, if not cleared by software within a specified interval, generates a nonmaskable interrupt. Furthermore, once watchdog timer operation is enabled, it cannot be disabled by software. The user can specify whether priority is placed on an interrupt based on the watchdog timer or on an interrupt based on the NMI pin.

Figure 8-14. Block Diagram of Watchdog Timer



9. INTERRUPT FUNCTION

Table 9-1 lists the interrupt request handling modes. These modes are selected by software.

Table 9-1.	Interrupt F	Request	Handling	Modes
------------	-------------	---------	----------	-------

Handling mode	Handled by	Handling	PC and PSW contents
Vectored interrupt	Software	Branches to a handling routine for execution (arbitrary handling).	The PC and PSW contents are pushed to and popped from the stack.
Context switching		Automatically selects a register bank, and branches to a handling routine for execution (arbitrary handling).	The PC and PSW contents are saved to and read from a fixed area in the register bank.
Macro service	Firmware	Performs operations such as memory-to-I/O- device data transfer (fixed handling).	Maintained

9.1 Interrupt Source

An interrupt can be issued from any one of the interrupt sources listed in Table 9-2: execution of a BRK instruction and BRKCS instruction, an operand error, or any of the 23 other interrupt sources.

Four levels of interrupt handling priority can be set. Priority levels can be set to nest control during interrupt handling or to concurrently generate interrupt requests. Nested macro services, however, are performed without suspension.

When interrupt requests having the same priority level are generated, they are handled according to the default priority (fixed). (See **Table 9-2**.)

Туре	Default		Source	Internal/	Macro			
туре	priority	Name	Trigger	external	service			
Software	-	BRK instruction	3RK instruction Instruction execution					
		BRKCS instruction						
		Operand error	When the MOV STBC,#byte, MOV WDM,#byte, or LOCATION instruction is executed, exclusive OR of the byte operand and byte does not produce FFH.					
Nonmaskable	-	NMI	Detection of edge input on the pin	External	-			
		WDT	Watchdog timer overflow	Internal				
Maskable	0 (highest)	INTP0	Detection of edge input on the pin (TM1/TM1W capture trigger, TM1/TM1W event counter input)	External	Enabled			
	1	INTP1	Detection of edge input on the pin (TM2/TM2W capture trigger, TM2/TM2W event counter input)					
	2	INTP2	Detection of edge input on the pin (TM2/TM2W capture trigger, TM2/TM2W event counter input)					
	3	INTP3	Detection of edge input on the pin (TM0 capture trigger, TM0 event counter input)					
	4	INTC00	TM0-CR00 match signal issued	Internal	Enabled			
	5	INTC01	TM0-CR01 match signal issued					
	6	INTC10	TM1-CR10 match signal issued (in 8-bit operation mode) TM1W-CR10W match signal issued (in 16-bit operation mode)					
	7	INTC11	TM1-CR11 match signal issued (in 8-bit operation mode) TM1W-CR11W match signal issued (in 16-bit operation mode)					
	8	INTC20	TM2-CR20 match signal issued (in 8-bit operation mode) TM2W-CR20W match signal issued (in 16-bit operation mode)					
	9	INTC21	TM2-CR21 match signal issued (in 8-bit operation mode) TM2W-CR21W match signal issued (in 16-bit operation mode)					
	10	INTC30	TM3-CR30 match signal issued (in 8-bit operation mode) TM3W-CR30W match signal issued (in 16-bit operation mode)					
	11	INTP4	Detection of edge input on the pin	External	Enabled			
	12	INTP5	Detection of edge input on the pin					
	13	INTAD	A/D converter processing completed (ADCR transfer)	Internal	Enabled			
	14	INTSER	ASI0 reception error		-			
	15	INTSR	ASI0 reception completed or CSI1 transfer completed		Enabled			
		INTCSI1						
	16	INTST	ASI0 transmission completed					
	17	INTCSI	CSI0 transfer completed					
	18	INTSER2	ASI2 reception error		-			
	19	INTSR2	ASI2 reception completed or CSI2 transfer completed		Enabled			
		INTCSI2						
	20 (lowest)	INTST2	ASI2 transmission completed					

Table 9-2. Interrupt Sources

Remark ASI: Asynchronous serial interface

CSI: Synchronous serial interface

9.2 Vectored Interrupt

When a branch to an interrupt handling routine occurs, the vector table address corresponding to the interrupt source is used as the branch address.

Interrupt handling by the CPU consists of the following operations :

- When a branch occurs : Push the CPU status (PC and PSW contents) to the stack.
- When control is returned: Pop the CPU status (PC and PSW contents) from the stack.

To return control from the handling routine to the main routine, use the RETI instruction. The branch destination addresses must be within the range of 0 to FFFFH.

Interrupt source	Vector table address
BRK instruction	003EH
Operand error	003CH
NMI	0002H
WDT	0004H
INTP0	0006H
INTP1	0008H
INTP2	000AH
INTP3	000CH
INTC00	000EH
INTC01	0010H
INTC10	0012H
INTC11	0014H
INTC20	0016H
INTC21	0018H
INTC30	001AH
INTP4	001CH
INTP5	001EH
INTAD	0020H
INTSER	0022H
INTSR	0024H
INTCSI1	
INTST	0026H
INTCSI	0028H
INTSER2	002AH
INTSR2	002CH
INTCSI2	
INTST2	002EH

Table 9-3. Vector Table Address	Table 9	9-3. \	Vector	Table	Address
---------------------------------	---------	---------------	--------	-------	---------

9.3 Context Switching

When an interrupt request is generated, or when the BRKCS instruction is executed, an appropriate register bank is selected by the hardware. Then, a branch to a vector address stored in that register bank occurs. At the same time, the contents of the current program counter (PC) and program status word (PSW) are stacked in the register bank.

The branch address must be within the range of 0 to FFFFH.

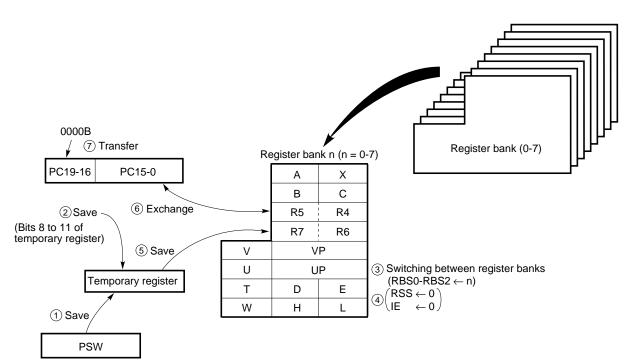


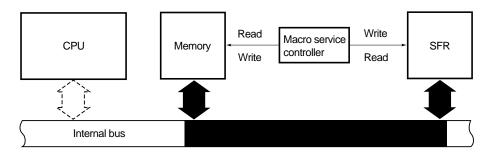
Figure 9-1. Context Switching Caused by an Interrupt Request

9.4 Macro Service

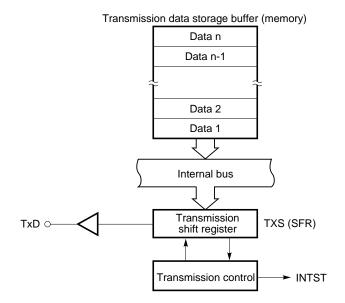
The macro service function enables data transfer between memory and special function registers (SFRs) without requiring the intervention of the CPU. The macro service controller accesses both memory and SFRs within the same transfer cycle to directly transfer data without having to perform data fetch.

Since the CPU status is neither saved nor restored, nor is data fetch performed, high-speed data transfer is possible.



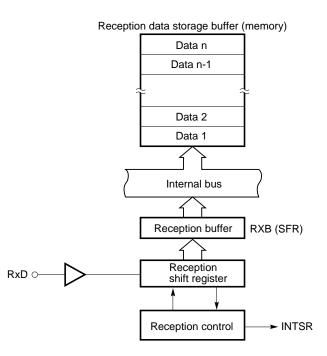


- 9.5 Examples of Macro Service Applications
- (1) Serial interface transmission



Each time macro service request (INTST) is generated, the next transmission data is transferred from memory to TXS. When data n (last byte) has been transferred to TXS (that is, once the transmission data storage buffer becomes empty), vectored interrupt request (INTST) is generated.

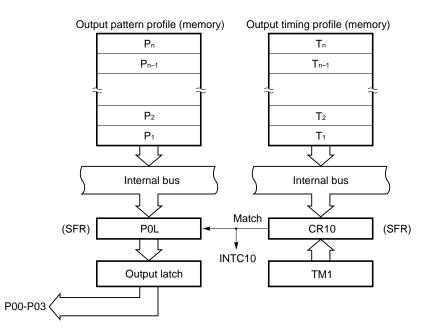
(2) Serial interface reception



Each time macro service request (INTSR) is generated, reception data is transferred from RXB to memory. When data n (last byte) has been transferred to memory (that is, once the reception data storage buffer becomes full), vectored interrupt request (INTSR) is generated.

(3) Real-time output port

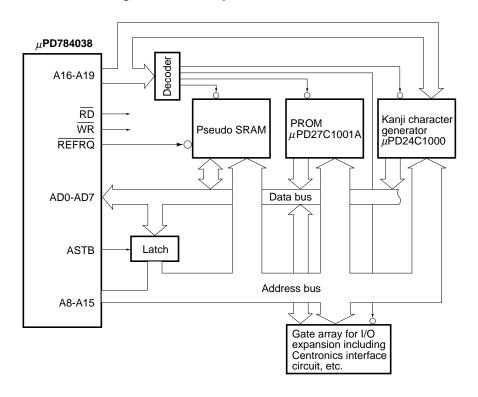
INTC10 and INTC11 function as the output triggers for the real-time output ports. For these triggers, the macro service can simultaneously set the next output pattern and interval. Therefore, INTC10 and INTC11 can be used to independently control two stepping motors. They can also be applied to PWM and DC motor control.

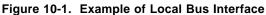


Each time macro service request (INTC10) is generated, a pattern and timing data are transferred to the buffer register (P0L) and compare register (CR10), respectively. When the contents of timer register 1 (TM1) and CR10 match, another INTC10 is generated, and the P0L contents are transferred to the output latch. When T_n (last byte) is transferred to CR10, vectored interrupt request (INTC10) is generated. For INTC11, the same operation as that performed for INTC10 is performed.

10. LOCAL BUS INTERFACE

The local bus interface enables the connection of external memory and I/O devices (memory-mapped I/O). It supports a 1M-byte memory space. (See **Figure 10-1**.)





10.1 Memory Expansion

By adding external memory, program memory or data memory can be expanded, 256 bytes at a time, to approximately 1M byte (seven steps).

10.2 Memory Space

The 1M-byte memory space is divided into eight spaces, each having a logical address. Each of these spaces can be controlled using the programmable wait and pseudo-static RAM refresh functions.

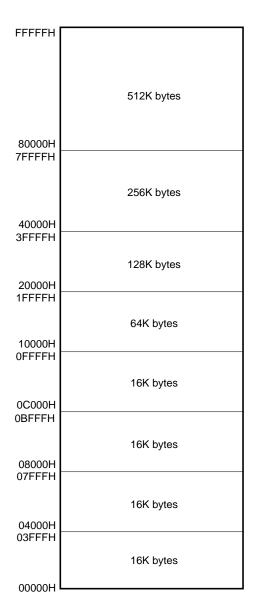


Figure 10-2. Memory Space

10.3 Programmable Wait

When the memory space is divided into eight spaces, a wait state can be separately inserted for each memory space while the \overline{RD} or \overline{WR} signal is active. This prevents the overall system efficiency from being degraded even when memory devices having different access times are connected.

In addition, an address wait function that extends the ASTB signal active period is provided to produce a longer address decode time. (This function is set for the entire space.)

10.4 Pseudo-Static RAM Refresh Function

Refresh is performed as follows:

- Pulse refresh
 A bus cycle is inserted where a refresh pulse is output on the REFRQ pin at regular intervals. When the memory space is divided into eight, and a specified area is being accessed, refresh pulses can also be output on the REFRQ pin as the memory is being accessed. This can prevent the refresh cycle from suspending normal memory access.
- Power-down self-refresh : In standby mode, a low-level signal is output on the REFRQ pin to maintain the contents of pseudo-static RAM.

10.5 Bus Hold Function

A bus hold function is provided to facilitate connection to devices such as a DMA controller. Suppose that a bus hold request signal (HLDRQ) is received from an external bus master. In this case, upon the completion of the bus cycle being performed, the address bus, address/data bus, ASTB, RD, and WR pins are placed in the high-impedance state, and the bus hold acknowledge signal (HLDAK) is made active to release the bus for the external bus master.

While the bus hold function is being used, the external wait and pseudo-static RAM refresh functions are disabled.

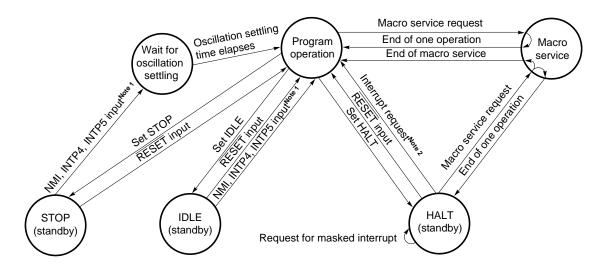
11. STANDBY FUNCTION

The standby function allows the power consumption of the chip to be reduced. The following standby modes are supported:

- HALT mode : The CPU operation clock is stopped. By occasionally inserting the HALT mode during normal operation, the overall average power consumption can be reduced.
- IDLE mode : The entire system is stopped, with the exception of the oscillator circuit. This mode consumes only very little more power than STOP mode, but normal program operation can be restored in almost as little time as that required to restore normal program operation from HALT mode.
- STOP mode: The oscillator is stopped. All operations in the chip stop, such that only leakage current flows.

These modes can be selected by software.

A macro service can be initiated in HALT mode.





Notes 1. INTP4 and INTP5 are applied when not masked.

- 2. Only when the interrupt request is not masked
- **Remark** NMI is enabled only by external input. The watchdog timer cannot be used to release one of the standby modes (STOP or IDLE mode).

12. RESET FUNCTION

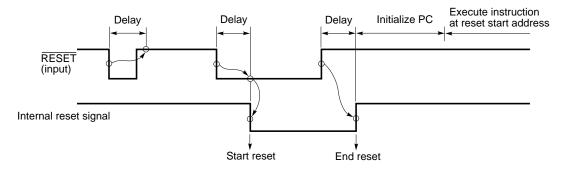
Applying a low-level signal to the RESET pin initializes the internal hardware (reset status). When the RESET input makes a low-to-high transition, the following data is loaded into the program counter (PC):

- Eight low-order bits of the PC : Contents of location at address 0000H
- · Intermediate eight bits of the PC : Contents of location at address 0001H
- Four high-order bits of the PC : 0

The PC contents are used as a branch destination address. Program execution starts from that address. Therefore, a reset start can be performed from an arbitrary address.

The contents of each register can be set by software, as required.

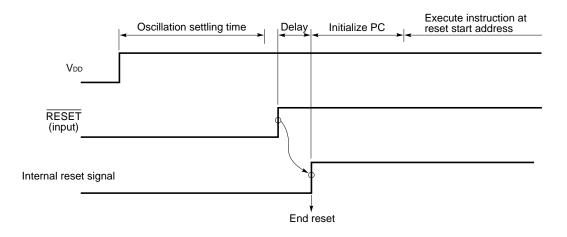
The RESET input circuit contains a noise eliminator to prevent malfunctions caused by noise. This noise eliminator is an analog delay sampling circuit.





For power-on reset, the RESET signal must be held active until the oscillation settling time (approximately 40 ms) has elapsed.

Figure 12-2. Power-On Reset



13. INSTRUCTION SET

(1) 8-bit instructions (The instructions enclosed in parentheses are implemented by a combination of operands, where A is described as r.)

MOV, XCH, ADD, ADDC, SUB, SUBC, AND, OR, XOR, CMP, MULU, DIVUW, INC, DEC, ROR, ROL, RORC, ROLC, SHR, SHL, ROR4, ROL4, DBNZ, PUSH, POP, MOVM, XCHM, CMPME, CMPMNE, CMPMNC, CMPMC, MOVBK, XCHBK, CMPBKE, CMPBKNE, CMPBKNC, CMPBKC, CHKL, CHKLA

2nd operand	#byte	А	r	saddr	sfr	!addr16	mem	r3	[WHL+]	n	NoneNote 2
			r'	saddr'		!!addr24	[saddrp]	PSWL	[WHL–]		
1st operand							[%saddrg]	PSWH			
A	(MOV)	(MOV)	MOV	(MOV)Note 6	MOV	(MOV)	MOV	MOV	(MOV)		
	ADDNote 1	(XCH)	ХСН	(XCH)Note 6	(XCH)	(XCH)	хсн		(XCH)		
		(ADD)Note 1	(ADD)Note 1	(ADD)Notes 1, 6	(ADD)Note 1	ADDNote 1	ADDNote 1		(ADD)Note 1		
r	MOV	(MOV)	MOV	MOV	MOV	MOV				RORNote 3	MULU
	ADDNote 1	(XCH)	хсн	хсн	хсн	хсн					DIVUW
		(ADD)Note 1	ADDNote 1	ADDNote 1	ADDNote 1						INC
											DEC
saddr	моу	(MOV)Note 6	MOV	MOV							INC
	ADDNote 1	(ADD)Note 1	ADDNote 1	хсн							DEC
				ADDNote 1							DBNZ
sfr	моу	MOV	MOV								PUSH
	ADDNote 1	(ADD)Note 1	ADDNote 1								POP
											CHKL
											CHKLA
!addr16	моу	(MOV)	MOV								
!!addr24		ADDNote 1									
mem		MOV									
[saddrp]		ADDNote 1									
[%saddrg]											
mem3											ROR4
											ROL4
r3	моу	MOV									
PSWL											
PSWH											
B, C											DBNZ
STBC, WDM	MOV										
[TDE+]		(MOV)							MOVBKNote 5		
[TDE-]		(ADD)Note 1									
		MOVMNote 4									

Table 13-1. Instructions Implemented by 8-Bit Addressing

Notes 1. ADDC, SUB, SUBC, AND, OR, XOR, and CMP are the same as ADD.

- 2. There is no second operand, or the second operand is not an operand address.
- 3. ROL, RORC, ROLC, SHR, and SHL are the same as ROR.
- 4. XCHM, CMPME, CMPMNE, CMPMNC, and CMPMC are the same as MOVM.
- 5. XCHBK, CMPBKE, CMPBKNE, CMPBKNC, and CMPBKC are the same as MOVBK.
- 6. When saddr is saddr2 with this combination, an instruction with a short code exists.

(2) 16-bit instructions (The instructions enclosed in parentheses are implemented by a combination of operands, where AX is described as rp.)

MOVW, XCHW, ADDW, SUBW, CMPW, MULUW, MULW, DIVUX, INCW, DECW, SHRW, SHLW, PUSH, POP, ADDWG, SUBWG, PUSHU, POPU, MOVTBLW, MACW, MACSW, SACW

2nd operand	#word	AX	rp	saddrp	sfrp	!addr16	mem	[WHL+]	byte	n	NoneNote 2
1st operand			rp'	saddrp'		!!addr24	[saddrp] [%saddrg]				
AX	(MOVW) ADDWNote 1	(MOVW) (XCHW) (ADD) ^{Note 1}	(MOVW) (XCHW) (ADDW) ^{Note 1}	(MOVW)Note 3 (XCHW)Note 3 (ADDW)Notes 1,3	MOVW (XCHW) (ADDW)Note 1	(MOVW) XCHW	MOVW XCHW	(MOVW) (XCHW)			
rp	MOVW ADDWNote 1	(MOVW) (XCHW) (ADDW)Note 1	MOVW XCHW ADDWNote 1	MOVW XCHW ADDWNote 1	MOVW XCHW ADDWNote 1	MOVW				SHRW SHLW	MULWNote 4 INCW DECW
saddrp	MOVW ADDWNote 1	(MOVW)Note 3 (ADDW)Note 1	MOVW ADDWNote 1	MOVW XCHW ADDWNote 1							INCW DECW
sfrp	MOVW ADDWNote 1	MOVW (ADDW)Note 1	MOVW ADDWNote 1								PUSH POP
!addr16 !!addr24	MOVW	(MOVW)	MOVW						MOVTBLW		
mem [saddrp] [%saddrg]		MOVW									
PSW											PUSH POP
SP	ADDWG SUBWG										
post											PUSH POP PUSHU POPU
[TDE+]		(MOVW)						SACW			
byte											MACW MACSW

Table 13-2. Instructions Implemented by 16-Bit Addressing

Notes 1. SUBW and CMPW are the same as ADDW.

- 2. There is no second operand, or the second operand is not an operand address.
- 3. When saddrp is saddrp2 with this combination, an instruction with a short code exists.
- **4.** MULUW and DIVUX are the same as MULW.

(3) 24-bit instructions (The instructions enclosed in parentheses are implemented by a combination of operands, where WHL is described as rg.) MOVG, ADDG, SUBG, INCG, DECG, PUSH, POP

2nd operand	#imm24	WHL	rg	saddrg	!!addr24	mem1	[%saddrg]	SP	None ^{Note}
1st operand			rg'						
WHL	(MOVG)	(MOVG)	(MOVG)	(MOVG)	(MOVG)	MOVG	MOVG	MOVG	
	(ADDG)	(ADDG)	(ADDG)	ADDG					
	(SUBG)	(SUBG)	(SUBG)	SUBG					
rg	MOVG	(MOVG)	MOVG	MOVG	MOVG				INCG
	ADDG	(ADDG)	ADDG						DECG
	SUBG	(SUBG)	SUBG						PUSH
									POP
saddrg		(MOVG)	MOVG						
!!addr24		(MOVG)	MOVG						
mem1		MOVG							
[%saddrg]		MOVG							
SP	MOVG	MOVG							INCG
									DECG

Table 13-3. Instructions Implemented by 24-Bit Addressing

Note There is no second operand, or the second operand is not an operand address.

(4) Bit manipulation instructions

MOV1, AND1, OR1, XOR1, SET1, CLR1, NOT1, BT, BF, BTCLR, BFSET

2nd operand	CY	saddr.bit sfr.bit	/saddr.bit /sfr.bit	NoneNote
		A.bit X.bit	/A.bit /X.bit	
		PSWL.bit PSWH.bit	/PSWL.bit /PSWH.bit	
		mem2.bit	/mem2.bit	
1st operand		!addr16.bit !!addr24.bit	/!addr16.bit /!!addr24.bit	
CY		MOV1	AND1	NOT1
		AND1	OR1	SET1
		OR1		CLR1
		XOR1		
saddr.bit	MOV1			NOT1
sfr.bit				SET1
A.bit				CLR1
X.bit				BF
PSWL.bit				BT
PSWH.bit				BTCLR
mem2.bit				BFSET
!addr16.bit				
!!addr24.bit				

Table 13-4. Bit Manipulation Instructions Implemented by Addressing

Note There is no second operand, or the second operand is not an operand address.

(5) Call/return instructions and branch instructions

CALL, CALLF, CALLT, BRK, RET, RETI, RETB, RETCS, RETCSB, BRKCS, BR, BNZ, BNE, BZ, BE, BNC, BNL, BC, BL, BNV, BPO, BV, BPE, BP, BN, BLT, BGE, BLE, BGT, BNH, BH, BF, BT, BTCLR, BFSET, DBNZ

Table 13-5. Call/Return and Branch Instructions Implemented by Addressing

Instruction address operand	\$addr20	\$!addr20	!addr16	‼addr20	rp	rg	[rp]	[rg]	!addr11	[addr5]	RBn	None
Basic instruction	BC ^{Note} BR	CALL BR	CALL BR RETCS RETCSB	CALL BR	CALL BR	CALL BR	CALL BR	CALL BR	CALLF	CALLF	BRKCS	BRK RET RETI RETB
Composite instruction	BF BT BTCLR BFSET DBNZ											

Note BNZ, BNE, BZ, BE, BNC, BNL, BL, BNV, BPO, BV, BPE, BP, BN, BLT, BGE, BLE, BGT, BNH, and BH are the same as BC.

(6) Other instructions

ADJBA, ADJBS, CVTBW, LOCATION, SEL, NOT, EI, DI, SWRS

14. ELECTRICAL CHARACTERISTICS

ABSOLUTE MAXIMUM RATINGS (TA = 25 $^{\circ}$ C)

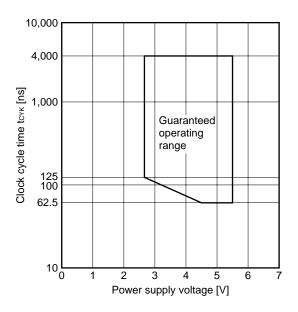
Parameter	Symbol	Conditions	Rating	Unit
Supply voltage	Vdd		-0.5 to +7.0	V
	AVDD		AVss to Vdd + 0.5	V
	AVss		-0.5 to +0.5	V
Input voltage	Vı		-0.5 to V _{DD} + 0.5	V
Output voltage	Vo		-0.5 to V _{DD} + 0.5	V
Output low current	lol	At one pin	15	mA
		Total of all output pins	100	mA
Output high current	Іон	At one pin	-10	mA
		Total of all output pins	-100	mA
A/D converter reference input voltage	AV _{REF1}		-0.5 to V _{DD} + 0.3	V
D/A converter reference input	AV _{REF2}		-0.5 to VDD + 0.3	V
voltage	AV _{REF3}		-0.5 to V _{DD} + 0.3	V
Operating ambient temperature	TA		-40 to +85	°C
Storage temperature	Tstg		-65 to +150	°C

Caution Absolute maximum ratings are rated values beyond which physical damage will be caused to the product; if the rated value of any of the parameters in the above table is exceeded, even momentarily, the quality of the product may deteriorate. Always use the product within its rated values.

OPERATING CONDITIONS

- Operating ambient temperature (T_A) : -40 to +85 °C
- Rise time and fall time (tr, tr) (at pins which are not specified) : 0 to 200 μs
- Power supply voltage and clock cycle time : See Figure 14-1.





CAPACITANCE (TA = 25 °C, VDD = Vss = 0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input capacitance	Ci	f = 1 MHz			10	pF
Output capacitance	Co	0 V on pins other than measured pins			10	pF
I/O capacitance	Сю				10	pF

Resonator	Recommended circuit	Parameter	MIN.	MAX.	Unit
Ceramic resonator or crystal	$V_{SS1} X1 X2$ $C1 - C2$ 777	Oscillator frequency (fxx)	4	32	MHz
External clock		X1 input frequency (fx)	4	32	MHz
	X1 X2	X1 input rise and fall times (txR, txF)	0	10	ns
	HCMOS inverter	X1 input high-level and low- level widths (twxH, twxL)	10	125	ns

OSCILLATOR CHARACTERISTICS (TA = -40 to +85 $^{\circ}$ C, VDD = +4.5 to 5.5 V, Vss = 0 V)

- Caution When using the system clock generator, run wires in the portion surrounded by broken lines according to the following rules to avoid effects such as stray capacitance:
 - Minimize the wiring.
 - Never cause the wires to cross other signal lines.
 - Never cause the wires to run near a line carrying a large varying current.
 - Cause the grounding point of the capacitor of the oscillator circuit to have the same potential as Vss1. Never connect the capacitor to a ground pattern carrying a large current.
 - Never extract a signal from the oscillator.

Resonator	Recommended circuit	Parameter	MIN.	MAX.	Unit
Ceramic resonator or crystal	$V_{SS1} X1 X2$ $C1 + C2$ $T77$	Oscillator frequency (fxx)	4	16	MHz
External clock		X1 input frequency (fx)	4	16	MHz
	X1 X2	X1 input rise and fall times (txR, txF)	0	10	ns
	HCMOS inverter	X1 input high-level and low- level widths (twxH, twxL)	10	125	ns

OSCILLATOR CHARACTERISTICS (TA = -40 to +85 $^{\circ}$ C, VDD = +2.7 to 5.5 V, Vss = 0 V)

Caution When using the system clock generator, run wires in the portion surrounded by broken lines according to the following rules to avoid effects such as stray capacitance:

- Minimize the wiring.
- Never cause the wires to cross other signal lines.
- Never cause the wires to run near a line carrying a large varying current.
- Cause the grounding point of the capacitor of the oscillator circuit to have the same potential as Vss1. Never connect the capacitor to a ground pattern carrying a large current.
- Never extract a signal from the oscillator.

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input low voltage	VIL1	For pins other than those described in Notes 1, 2, 3, and 4	-0.3		0.3Vdd	V
	VIL2	For pins described in Notes 1, 2, 3, and 4	-0.3		0.2Vdd	V
	VIL3	V_{DD} = +5.0 V \pm 10 % For pins described in Notes 2, 3, and 4	-0.3		+0.8	V
Input high voltage	VIH1	For pins other than those described in Note 1	0.7Vdd		Vdd + 0.3	V
	VIH2	For pins described in Note 1	0.8Vdd		VDD + 0.3	V
	Vінз	V_{DD} = +5.0 V \pm 10 % For pins described in Notes 2, 3, and 4	2.2		Vdd + 0.3	V
Output low voltage	Vol1	IoL = 2 mA		0.4	V	
	Vol2	V_{DD} = +5.0 V ± 10 % IoL = 8 mA For pins described in Notes 2 and 5			1.0	V
Output high voltage	Vон1	юн = -2 mA	Vdd - 1.0			V
	Voh2	V_{DD} = +5.0 V ± 10 % I _{OH} = -5 mA For pins described in Note 4	Vdd - 1.4			V
X1 input low current	IL.	$ \begin{aligned} EXTC &= 0 \\ 0 \ V &\leq V_{I} &\leq V_{IL2} \end{aligned} $			-30	μΑ
X1 input high current	Ін	$\begin{array}{l} EXTC = 0 \\ V_{IH2} \leq V_{I} \leq V_{DD} \end{array}$			+30	μA

- Notes 1. X1, X2, RESET, P12/ASCK2/SCK2, P20/NMI, P21/INTP0, P22/INTP1, P23/INTP2/CI, P24/INTP3, P25/INTP4/ASCK/SCK1, P26/INTP5, P27/SI0, P32/SCK0/SCL, P33/SO0/SDA, TEST
 - **2.** P40/AD0-P47/AD7, P50/A8-P57/A15
 - **3.** P60/A16-P63/A19, P64/RD, P65/WR, P66/WAIT/HLDRQ, P67/REFRQ/HLDAK
 - 4. P00-P07
 - 5. P10-P17

Parameter	Symbol	Co	onditions	MIN.	TYP.	MAX.	Unit
Input leakage current	lu	$0 V \le V_I \le V_{DD}$ For pins other that	n X1 when EXTC = 0			±10	μA
Output leakage current	Ilo	$0 V \le V_0 \le V_{DD}$				±10	μA
VDD supply current	IDD1	Operation mode	fxx = 32 MHz Vdd = +5.0 V ± 10 %		25	45	mA
			fxx = 16 MHz V _{DD} = +2.7 to 3.3 V		12	25	mA
	IDD2	HALT mode	fxx = 32 MHz Vdd = +5.0 V ± 10 %		13	26	mA
			fxx = 16 MHz V _{DD} = +2.7 to 3.3 V		8	12	mA
	Іддз	IDLE mode (EXTC = 0)	fxx = 32 MHz Vdd = +5.0 V ± 10 %			12	mA
			fxx = 16 MHz V _{DD} = +2.7 to 3.3 V			8	mA
Pull-up resistor	R∟	$V_{I} = 0 V$		15		80	kΩ

DC CHARACTERISTICS (T_A = -40 to +85 °C, V_{DD} = AV_{DD} = +2.7 to 5.5 V, V_{SS} = AV_{SS} = 0 V) (2/2)

AC CHARACTERISTICS (TA = -40 to +85 °C, VDD = AVDD = +2.7 to 5.5 V, Vss = AVss = 0 V)

(1) Read/write operation (1/2)

Parameter	Symbol	c	onditions	MIN.	MAX.	Unit
Address setup time	t sast	$V_{DD} = +5.0 V \pm$: 10 %	(0.5 + a) T - 15		ns
				(0.5 + a) T - 31		ns
ASTB high-level width	twsтн	VDD = +5.0 V ±	: 10 %	(0.5 + a) T - 17		ns
				(0.5 + a) T - 40		ns
Address hold time (to ASTB \downarrow)	t HSTLA	VDD = +5.0 V ±	: 10 %	0.5T - 24		ns
				0.5T - 34		ns
Address hold time (to $\overline{RD}\uparrow$)	t hra			0.5T - 14		ns
Delay from address to $\overline{\mathrm{RD}} {\downarrow}$	t dar	$V_{DD} = +5.0 V \pm$: 10 %	(1 + a) T - 9		ns
				(1 + a) T - 15		ns
Address float time (to $\overline{RD}\downarrow$)	t fra				0	ns
Delay from address to data input	tdaid	$V_{DD} = +5.0 V \pm$: 10 %		(2.5 + a + n) T - 37	ns
					(2.5 + a + n) T - 52	ns
Delay from ASTB \downarrow to data input	tostid	$V_{DD} = +5.0 V \pm$: 10 %		(2 + n) T - 40	ns
					(2 + n) T - 60	ns
Delay from $\overline{RD}\downarrow$ to data input	tdrid	$V_{DD} = +5.0 V \pm$: 10 %		(1.5 + n) T - 50	ns
					(1.5 + n) T - 70	ns
Delay from ASTB \downarrow to $\overline{\text{RD}}\downarrow$	t dstr			0.5T - 9		ns
Data hold time (to \overline{RD})	thrid			0		ns
Delay from $\overline{RD} \uparrow$ to address active	t dra	After program	$V_{DD} = +5.0 V \pm 10 \%$	0.5T - 8		ns
		is read		0.5T - 12		ns
		After data is	$V_{DD} = +5.0 V \pm 10 \%$	1.5T - 8		ns
		read		1.5T - 12		ns
Delay from $\overline{RD}\uparrow$ to $ASTB\uparrow$	t drst			0.5T - 17		ns
RD low-level width	twrl	VDD = +5.0 V ±	: 10 %	(1.5 + n) T - 30		ns
				(1.5 + n) T - 40		ns
Address hold time (to \overline{WR}^{\uparrow})	t HWA			0.5T - 14		ns
Delay from address to $\overline{WR} {\downarrow}$	tdaw	VDD = +5.0 V ±	: 10 %	(1 + a) T - 5		ns
				(1 + a) T - 15		ns
Delay from ASTB \downarrow to data output	t DSTOD	VDD = +5.0 V ±	: 10 %		0.5T + 19	ns
					0.5T + 35	ns
Delay from $\overline{WR} \downarrow$ to data output	towod				0.5T - 11	ns
Delay from ASTB \downarrow to $\overline{WR}\downarrow$	t DSTW			0.5T - 9		ns

Remarks T: TCYK (system clock cycle time)

a: 1 (during address wait), otherwise, 0

n: Number of wait states (n \ge 0)

(1) Read/write operation (2/2)

Parameter	Symbol	Conditions	MIN.	MAX.	Unit
Data setup time (to $\overline{WR}\uparrow$)	tsodw	VDD = +5.0 V ± 10 %	(1.5 + n) T - 30		ns
			(1.5 + n) T - 40		ns
Data hold time (to WR↑)Note	thwod	VDD = +5.0 V ± 10 %	0.5T - 5		ns
			0.5T - 25		ns
Delay from WR↑ to ASTB↑	t DWST		0.5T - 12		ns
WR low-level width	tww∟	VDD = +5.0 V ± 10 %	(1.5 + n) T - 30		ns
			(1.5 + n) T - 40		ns

Note The hold time includes the time during which V_{OH1} and V_{OL1} are held under the load conditions of C_L = 50 pF and R_L = 4.7 k Ω .

Remarks T: TCYK (system clock cycle time)

n: Number of wait states $(n \ge 0)$

(2) Bus hold timing

Parameter	Symbol	Conditions	MIN.	MAX.	Unit
Delay from HLDRQ↑ to float	tғнас			(6 + a + n) T + 50	ns
Delay from HLDRQ↑ to HLDAK↑	tdhqhhah	Vdd = +5.0 V ± 10 %		(7 + a + n) T + 30	ns
				(7 + a + n) T + 40	ns
Delay from float to HLDAK↑	t DCFHA			1T + 30	ns
Delay from HLDRQ \downarrow to HLDAK \downarrow		VDD = +5.0 V ± 10 %		2T + 40	ns
				2T + 60	ns
Delay from HLDAK↓ to active	t DHAC	V_{DD} = +5.0 V ± 10 %	1T - 20		ns
			1T - 30		ns

Remarks T: TCYK (system clock cycle time)

- a: 1 (during address wait), otherwise, 0
- n: Number of wait states $(n \ge 0)$

(3) External wait timing

Parameter	Symbol	Conditions	MIN.	MAX.	Unit
Delay from address to $\overline{\text{WAIT}} {\downarrow}$ input	t dawt	V_{DD} = +5.0 V ± 10 %		(2 + a) T - 40	ns
				(2 + a) T - 60	ns
Delay from ASTB \downarrow to $\overline{\text{WAIT}}\downarrow$ input	t DSTWT	VDD = +5.0 V ± 10 %		1.5T - 40	ns
				1.5T - 60	ns
Hold time from ASTB \downarrow to WAIT	tнsтwтн	VDD = +5.0 V ± 10 %	(0.5 + n) T + 5		ns
			(0.5 + n) T +10		ns
Delay from ASTB↓ to WAIT↑	t DSTWTH	VDD = +5.0 V ± 10 %		(1.5 + n) T - 40	ns
				(1.5 + n) T - 60	ns
Delay from $\overline{RD} \downarrow$ to $\overline{WAIT} \downarrow$ input	t drwtl	VDD = +5.0 V ± 10 %		T - 50	ns
				T - 70	ns
Hold time from $\overline{RD}\downarrow$ to $\overline{WAIT}\downarrow$	t HRWT	VDD = +5.0 V ± 10 %	nT + 5		ns
			nT + 10		ns
Delay from $\overline{RD}\downarrow$ to $\overline{WAIT}\uparrow$	t drwth	VDD = +5.0 V ± 10 %		(1 + n) T - 40	ns
				(1 + n) T - 60	ns
Delay from \overline{WAIT} to data input	towtid	VDD = +5.0 V ± 10 %		0.5T - 5	ns
				0.5T - 10	ns
Delay from \overline{WAIT} to \overline{WR}	t dwtw		0.5T		ns
Delay from \overline{WAIT} to \overline{RD}	t dwtr		0.5T		ns
Delay from $\overline{WR}{\downarrow}$ to $\overline{WAIT}{\downarrow}$ input	t dwwtl	VDD = +5.0 V ± 10 %		T - 50	ns
				T - 75	ns
Hold time from $\overline{\mathrm{WR}}\downarrow$ to $\overline{\mathrm{WAIT}}$	tнwwт	VDD = +5.0 V ± 10 %	nT + 5		ns
			nT + 10		ns
Delay from $\overline{WR} \downarrow$ to $\overline{WAIT} \uparrow$	t DWWTH	VDD = +5.0 V ± 10 %		(1 + n) T - 40	ns
				(1 + n) T - 70	ns

Remarks T: TCYK (system clock cycle time)

- a: 1 (during address wait), otherwise, 0
- n: Number of wait states (n \ge 0)

(4) Refresh timing

Parameter	Symbol	Conditions	MIN.	MAX.	Unit
Random read/write cycle time	t RC		ЗТ		ns
REFRQ low-level pulse width	twrfql	VDD = +5.0 V ± 10 %	1.5T - 25		ns
			1.5T - 30		ns
Delay from ASTB↓ to REFRQ	t DSTRFQ		0.5T - 9		ns
Delay from RD↑ to REFRQ	t drrfq		1.5T - 9		ns
Delay from WR↑ to REFRQ	t dwrfq		1.5T - 9		ns
Delay from REFRQ↑ to ASTB	t DRFQST		0.5T - 15		ns
REFRQ high-level pulse width	twrfqh	VDD = +5.0 V ± 10 %	1.5T - 25		ns
			1.5T - 30		ns

Remark T: TCYK (system clock cycle time)

SERIAL OPERATION (TA = -40 to +85 $^{\circ}$ C, VDD = +2.7 to 5.5 V, AVss = Vss = 0 V)

(1) CSI

Parameter	Symbol		Conditions	MIN.	MAX.	Unit
Serial clock cycle time (SCK0)	tсүѕко	Input	External clock When SCK0 and SO0 are CMOS I/O	10/fxx + 380		ns
		Outpu	t	Т		μs
Serial clock low-level width (SCK0)	twsklo	Input	External clock When SCK0 and SO0 are CMOS I/O	5/fxx + 150		ns
		Outpu	t	0.5T - 40		μs
Serial clock high-level width (SCK0)	twsкнo	Input	External clock When SCK0 and SO0 are CMOS I/O	5/fxx + 150		ns
		Outpu	t	0.5T - 40		μs
SI0 setup time (to SCK0↑)	tsssko			40		ns
SI0 hold time (to SCK0↑)	tнssкo			5/fxx + 40		ns
SO0 output delay time (to SCK0↓)	tdsbsk1		S push-pull output e serial I/O mode)	0	5/fxx + 150	ns
	tdsbsk2		drain output e serial I/O mode), R∟ = 1 kΩ	0	5/fxx + 400	ns

Remarks 1. The values in this table are those when C_{L} is 100 pF.

- 2. T : Serial clock cycle set by software. The minimum value is 16/fxx.
- **3.** fxx: Oscillator frequency

(2) IOE1, IOE2

Parameter	Symbol		Conditions	MIN.	MAX.	Unit
Serial clock cycle time	tcysk1	Input	V_{DD} = +5.0 V \pm 10 %	250		ns
(SCK1, SCK2)				500		ns
		Output	Internal, divided by 16	Т		ns
Serial clock low-level width	twskl1	Input	$V_{DD} = +5.0 \text{ V} \pm 10 \%$	85		ns
(SCK1, SCK2)				210		ns
		Output	Internal, divided by 16	0.5T - 40		ns
Serial clock high-level width	twskH1	Input	$V_{DD} = +5.0 \text{ V} \pm 10 \%$	85		ns
(SCK1, SCK2)				210		ns
		Output	Internal, divided by 16	0.5T - 40		ns
Setup time for SI1 and SI2 (to SCK1, SCK2↑)	tsssk1			40		ns
Hold time for SI1 and SI2 (to SCK1, SCK2↑)	thssk1			40		ns
Output delay time for SO1 and SO2 (to $\overline{SCK1}, \overline{SCK2}\downarrow$)	t DSOSK			0	50	ns
Output hold time for SO1 and SO2 (to SCK1, SCK2↑)	tнsosк	When da	ata is transferred	0.5tсүsк1 - 40		ns

Remarks 1. The values in this table are those when C_L is 100 pF.

2. T: Serial clock cycle set by software. The minimum value is 16/fxx.

(3) UART, UART2

Parameter	Symbol	Conditions	MIN.	MAX.	Unit
ASCK clock input cycle time	t CYASK	V_{DD} = +5.0 V ± 10 %	125		ns
			250		ns
ASCK clock low-level width	tWASKL	VDD = +5.0 V ± 10 %	52.5		ns
			85		ns
ASCK clock high-level width	t waskh	VDD = +5.0 V ± 10 %	52.5		ns
			85		ns

CLOCK OUTPUT OPERATION

Parameter	Symbol	Conditions	MIN.	MAX.	Unit
CLKOUT cycle time	tcvc∟		nT		ns
CLKOUT low-level width	tCLL	VDD = +5.0 V ± 10 %	0.5tcrc∟ - 10		ns
			0.5tcycL - 20		ns
CLKOUT high-level width	t CLH	VDD = +5.0 V ± 10 %	0.5tcrc∟ - 10		ns
			0.5tcycL - 20		ns
CLKOUT rise time	t CLR	VDD = +5.0 V ± 10 %		10	ns
				20	ns
CLKOUT fall time	t CLF	$V_{DD} = +5.0 V \pm 10 \%$		10	ns
				20	ns

Remarks n: Divided frequency ratio set by software in the CPU (n = 1, 2, 4, 8, 16) T: Τcyk (system clock cycle time)

OTHER OPERATIONS

	Parameter	Symbol	Conditions	MIN.	MAX.	Unit
	NMI low-level width	twnil		10		μs
	NMI high-level width	twniн		10		μs
*	INTP0 low-level width	t WITOL		4tcysmp		ns
*	INTP0 high-level width	twiтон		4tcysmp		ns
*	Low-level width for INTP1- INTP3 and CI	t wi⊤1L		4tcycpu		ns
*	High-level width for INTP1- INTP3 and CI	twit1H		4tcycpu		ns
	Low-level width for INTP4 and INTP5	t wit2L		10		μs
	High-level width for INTP4 and INTP5	twit2H		10		μs
	RESET low-level width	twrsl		10		μs
	RESET high-level width	twrsh		10		μs

Remarks tCYSMP: Sampling clock set by software

tCYCPU: CPU operation clock set by software in the CPU

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Resolution			8			bit
Total errorNote					1.0	%
Linearity calibrationNote					0.8	%
Quantization error					±1/2	LSB
Conversion time	t CONV	FR = 1	120			tсүк
		FR = 0	180			tсүк
Sampling time	t SAMP	FR = 1	24			tсүк
		FR = 0	36			tсүк
Analog input voltage	VIAN		-0.3		AV _{REF1} + 0.3	V
Analog input impedance	Ran			1,000		MΩ
AVREF1 current	AIREF1			0.5	1.5	mA
AVDD supply current	Aldd1	fxx = 32 MHz, CS = 1		2.0	5.0	mA
	AIDD2	STOP mode, CS = 0		1.0	20	μA

A/D CONVERTER CHARACTERISTICS (TA = -40 to +85 °C, VDD = AVDD = AVREF1 = +2.7 to 5.5 V, Vss = AVss = 0 V)

Note Quantization error is not included. This parameter is indicated as the ratio to the full-scale value.

Remark tcyk: System clock cycle time

D/A CONVERTER CHARACTERISTICS (T_A = -40 to +85 $^{\circ}$ C, V_{DD} = AV_{DD} = +2.7 to 5.5 V, V_{SS} = AV_{SS} = 0 V)

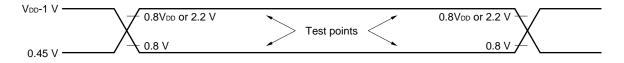
Parameter	Symbol	Co	onditions	MIN.	TYP.	MAX.	Unit
Resolution				8			bit
Total error		Load conditions: 4 MΩ, 30 pF	V _{DD} = AV _{DD} = AV _{REF2} = +2.7 to 5.5 V AV _{REF3} = 0 V			0.6	%
			V _{DD} = AV _{DD} = +2.7 to 5.5 V AV _{REF2} = 0.75V _{DD} AV _{REF3} = 0.25V _{DD}			0.8	%
		Load conditions: 2 MΩ, 30 pF	V _{DD} = AV _{DD} = AV _{REF2} = +2.7 to 5.5 V AV _{REF3} = 0 V			0.8	%
			VDD = AVDD = +2.7 to 5.5 V AVREF2 = 0.75VDD AVREF3 = 0.25VDD			1.0	%
Settling time		Load conditions:	2 MΩ, 30 pF			10	μs
Output resistance	Ro	DACS0, 1 = 55 H	ł		10		kΩ
Analog reference voltage	AV _{REF2}			0.75Vdd		Vdd	V
	AV _{REF3}			0		0.25Vdd	V
Resistance of AVREF2 and AVREF3	RAIREF	DACS0, 1 = 55 H	l	4	8		kΩ
Reference power supply	AIREF2			0		5	mA
input current	AIREF3			-5		0	mA

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Data retention voltage	Vdddr	STOP mode	2.5		5.5	V
Data retention current	Idddr	VDDDR = +2.7 to 5.5 V		10	50	μA
		VDDDR = +2.5 V		2	10	μA
VDD rise time	trvd		200			μs
VDD fall time	t fvd		200			μs
V _{DD} hold time (to STOP mode setting)	t hvd		0			ms
STOP clear signal input time	t DREL		0			ms
Oscillation settling time	twait	Crystal	30			ms
		Ceramic resonator	5			ms
Input low voltage	VIL	Specific pins ^{Note}	0		0.1Vdddr	V
Input high voltage	Vih		0.9Vdddr		Vdddr	V

DATA RETENTION CHARACTERISTICS (T_A = -40 to +85 °C)

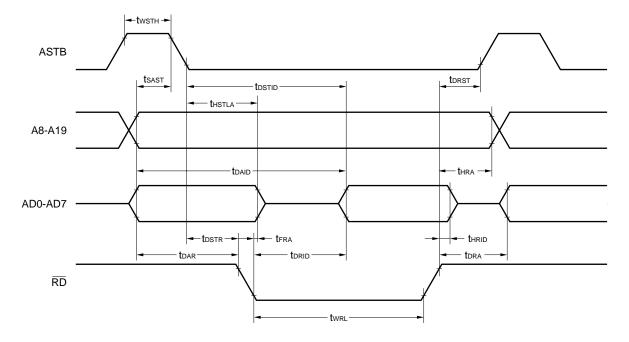
Note RESET, P20/NMI, P21/INTP0, P22/INTP1, P23/INTP2/CI, P24/INTP3, P25/INTP4/ASCK/SCK1, P26/INTP5, P27/SI0, P32/SCK0/SCL, and P33/SO0/SDA pins

AC TIMING TEST POINTS

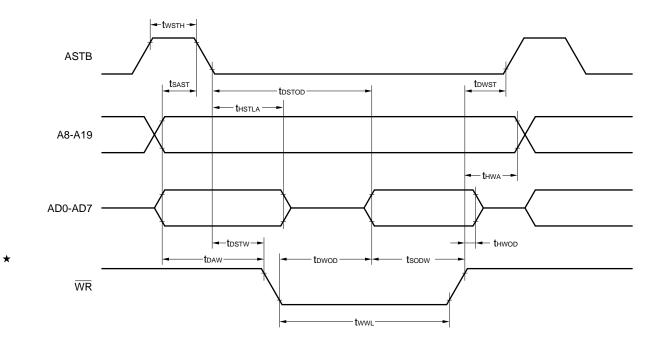


TIMING WAVEFORM

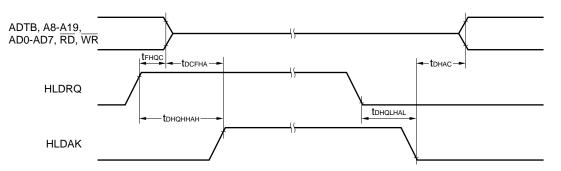
(1) Read operation



(2) Write operation

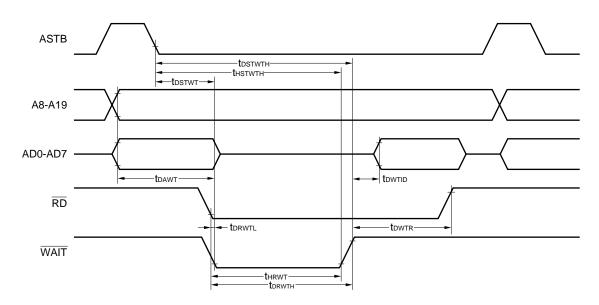


HOLD TIMING

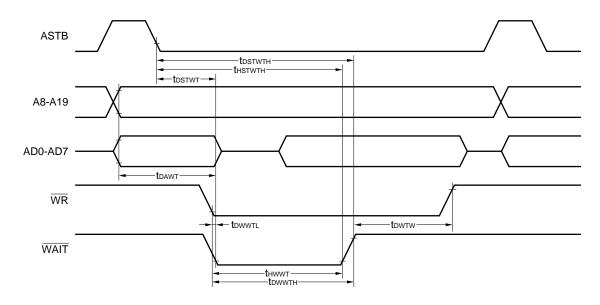


EXTERNAL WAIT SIGNAL INPUT TIMING

(1) Read operation

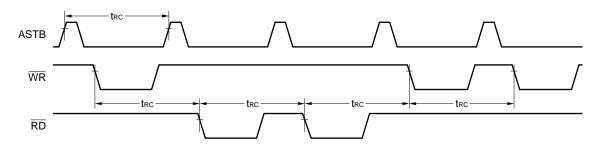


(2) Write operation

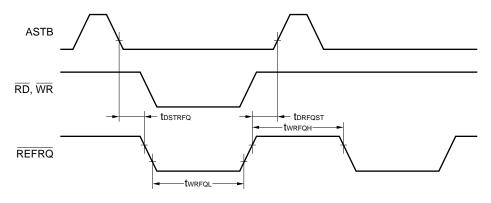


REFRESH TIMING WAVEFORM

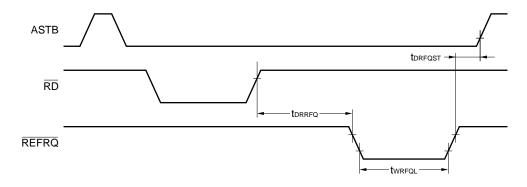
(1) Random read/write cycle



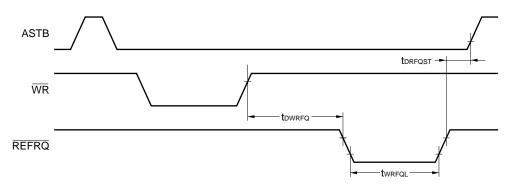
(2) When refresh memory is accessed for a read and write at the same time



(3) Refresh after a read



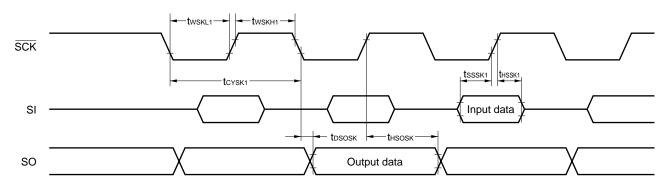
(4) Refresh after a write



★

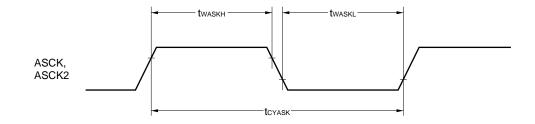
(2) IOE1, IOE2

SO

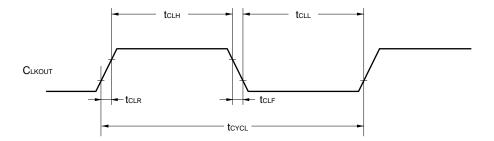


Output data

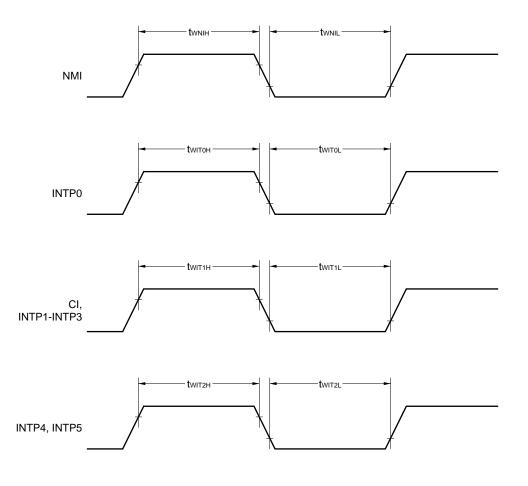
(3) UART, UART2



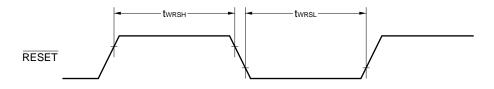
CLOCK OUTPUT TIMING



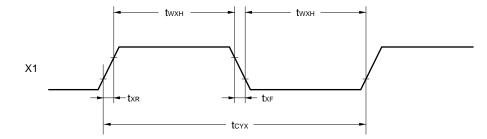
INTERRUPT INPUT TIMING



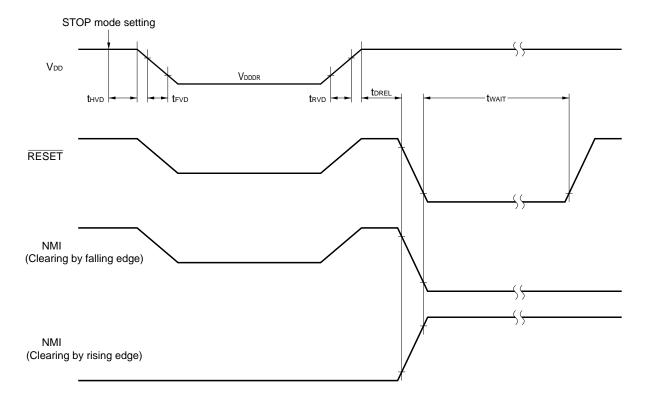
RESET INPUT TIMING



EXTERNAL CLOCK TIMING

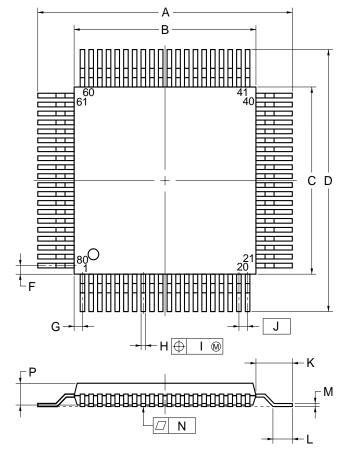


DATA RETENTION CHARACTERISTICS

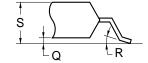


15. PACKAGE DRAWINGS

80 PIN PLASTIC QFP (14x14)



detail of lead end



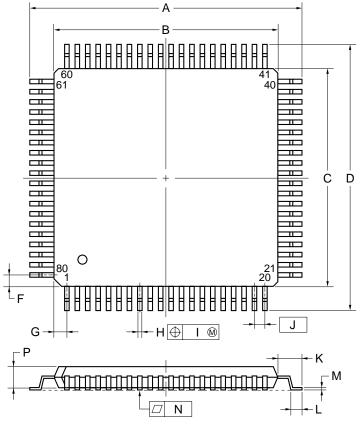
NOTE

Each lead centerline is located within 0.13 mm (0.005 inch) of its true position (T.P.) at maximum material condition.

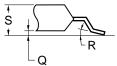
ITEM	MILLIMETERS	INCHES
А	17.2±0.4	0.677±0.016
В	14.0±0.2	$0.551\substack{+0.009\\-0.008}$
С	14.0±0.2	$0.551^{+0.009}_{-0.008}$
D	17.2±0.4	0.677±0.016
F	0.825	0.032
G	0.825	0.032
Н	0.30±0.10	0.012 ^{+0.004} -0.005
I	0.13	0.005
J	0.65 (T.P.)	0.026 (T.P.)
К	1.6±0.2	0.063±0.008
L	0.8±0.2	$0.031^{+0.009}_{-0.008}$
М	$0.15^{+0.10}_{-0.05}$	$0.006^{+0.004}_{-0.003}$
Ν	0.10	0.004
Р	2.7±0.1	$0.106^{+0.005}_{-0.004}$
Q	0.1±0.1	0.004±0.004
R	5°±5°	5°±5°
S	3.0 MAX.	0.119 MAX.
		S80GC-65-3B9-5

Remark The shape and material of the ES version are the same as those of the corresponding mass-produced product.

80 PIN PLASTIC QFP (14×14)







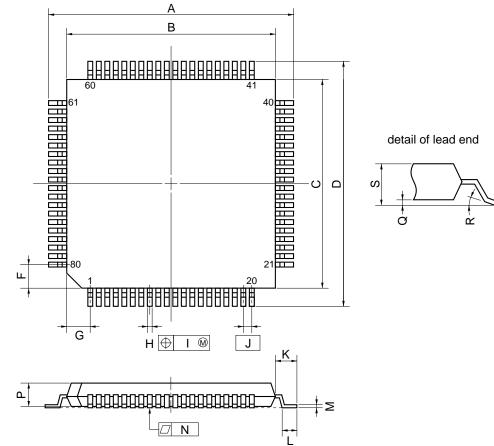
NOTE

Each lead centerline is located within 0.13 mm (0.005 inch) of its true position (T.P.) at maximum material condition.

ITEM	MILLIMETERS	INCHES
А	17.20±0.20	0.677±0.008
В	14.00±0.20	0.551 +0.009 -0.008
С	14.00±0.20	$0.551^{+0.009}_{-0.008}$
D	17.20±0.20	0.677±0.008
F	0.825	0.032
G	0.825	0.032
Н	0.32±0.06	0.013 ^{+0.002} -0.003
I	0.13	0.005
J	0.65 (T.P.)	0.026 (T.P.)
K	1.60±0.20	0.063±0.008
L	0.80±0.20	$0.031^{+0.009}_{-0.008}$
М	$0.17 \substack{+0.03 \\ -0.07}$	$0.007 \substack{+0.001 \\ -0.003}$
Ν	0.10	0.004
P	1.40±0.10	0.055±0.004
Q	0.125±0.075	0.005±0.003
R	3°+7° -3°	3°+7° -3°
S	1.70 MAX.	0.067 MAX.
		P80GC-65-8BT

Remark The shape and material of the ES version are the same as those of the corresponding mass-produced product.

80 PIN PLASTIC TQFP (FINE PITCH) (12)





Each lead centerline is located within 0.10 mm (0.004 inch) of its true position (T.P.) at maximum material condition.

ITEM	MILLIMETERS	INCHES
А	14.0±0.2	$0.551^{+0.009}_{-0.008}$
В	12.0±0.2	$0.472^{+0.009}_{-0.008}$
С	12.0±0.2	$0.472^{+0.009}_{-0.008}$
D	14.0±0.2	$0.551^{+0.009}_{-0.008}$
F	1.25	0.049
G	1.25	0.049
Н	$0.22^{+0.05}_{-0.04}$	0.009±0.002
I	0.10	0.004
J	0.5 (T.P.)	0.020 (T.P.)
к	1.0±0.2	$0.039^{+0.009}_{-0.008}$
L	0.5±0.2	$0.020^{+0.008}_{-0.009}$
М	$0.145^{+0.055}_{-0.045}$	0.006±0.002
N	0.10	0.004
Р	1.05	0.041
Q	0.05±0.05	0.002±0.002
R	5°±5°	5°±5°
S	1.27 MAX.	0.050 MAX.
		P80GK-50-BE9-4

Remark The shape and material of the ES version are the same as those of the corresponding mass-produced product.

NEC

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16. RECOMMENDED SOLDERING CONDITIONS

The conditions listed below shall be met when soldering the μ PD784035, μ PD784036, μ PD784037, or μ PD784038.

For details of the recommended soldering conditions, refer to our document **Semiconductor Device Mounting Technology Manual** (C10535E).

Please consult with our sales offices in case any other soldering process is used, or in case soldering is done under different conditions.

Table 16-1. Soldering Conditions for Surface-Mount Devices (1/2)

 (1) μPD784035GC-xxx-3B9: 80-pin plastic QFP (14 × 14 × 2.7 mm) μPD784036GC-xxx-3B9: 80-pin plastic QFP (14 × 14 × 2.7 mm) μPD784037GC-xxx-3B9: 80-pin plastic QFP (14 × 14 × 2.7 mm) μPD784038GC-xxx-3B9: 80-pin plastic QFP (14 × 14 × 2.7 mm)

Soldering process	Soldering conditions	Symbol
Infrared ray reflow	Peak package's surface temperature: 235 °C Reflow time: 30 seconds or less (210 °C or more) Maximum allowable number of reflow processes: 3	IR35-00-3
VPS	Peak package's surface temperature: 215 °C Reflow time: 40 seconds or less (200 °C or more) Maximum allowable number of reflow processes: 3	VP15-00-3
Wave soldering	Solder temperature: 260 °C or less Flow time: 10 seconds or less Number of flow processes: 1 Preheating temperature : 120 °C max. (measured on the package surface)	WS60-00-1
Partial heating method	Terminal temperature: 300 °C or less Heat time: 3 seconds or less (for one side of a device)	-

Caution Do not apply two or more different soldering methods to one chip (except for partial heating method for terminal sections).

(2) $\mu\text{PD784035GC-xxx-8BT:}$ 80-pin plastic QFP (14 \times 14 \times 1.4 mm)

 $\mu \text{PD784036GC-}{\times}{\times}{\times}{\text{-8BT:}}$ 80-pin plastic QFP (14 \times 14 \times 1.4 mm)

 $\mu\text{PD784037GC-}{\times}{\times}{\times}{-8BT:}$ 80-pin plastic QFP (14 \times 14 \times 1.4 mm)

 μ PD784038GC-×××-8BT: 80-pin plastic QFP (14 × 14 × 1.4 mm)

Soldering process	Soldering conditions	Symbol
Infrared ray reflow	Peak package's surface temperature: 235 °C Reflow time: 30 seconds or less (210 °C or more) Maximum allowable number of reflow processes: 2	IR35-00-2
VPS	Peak package's surface temperature: 215 °C Reflow time: 40 seconds or less (200 °C or more) Maximum allowable number of reflow processes: 2	VP15-00-2
Wave soldering	Solder temperature: 260 °C or less Flow time: 10 seconds or less Number of flow processes: 1 Preheating temperature : 120 °C max. (measured on the package surface)	WS60-00-1
Partial heating method	Terminal temperature: 300 °C or less Heat time: 3 seconds or less (for one side of a device)	-

Caution Do not apply two or more different soldering methods to one chip (except for partial heating method for terminal sections).

Table 16-1. Soldering Conditions for Surface-Mount Devices (2/2)

(3) μ PD784035GK- \times -BE9: 80-pin plastic TQFP (fine pitch) (12 × 12 mm) μ PD784036GK- \times -BE9: 80-pin plastic TQFP (fine pitch) (12 × 12 mm) μ PD784037GK- \times -BE9: 80-pin plastic TQFP (fine pitch) (12 × 12 mm) μ PD784038GK- \times -BE9: 80-pin plastic TQFP (fine pitch) (12 × 12 mm)

Soldering process	Soldering conditions	Symbol
Infrared ray reflow	Peak package's surface temperature: 235 °C Reflow time: 30 seconds or less (210 °C or more) Maximum allowable number of reflow processes: 2 Exposure limit: 7 daysNote (10 hours of pre-baking is required at 125 °C afterward) <caution> Non-heat-resistant trays, such as magazine and taping trays, cannot be baked before unpacking.</caution>	IR35-107-2
VPS	Peak package's surface temperature: 215 °C Reflow time: 40 seconds or less (200 °C or more) Maximum allowable number of reflow processes: 2 Exposure limit: 7 daysNote (10 hours of pre-baking is required at 125 °C afterward) <caution> Non-heat-resistant trays, such as magazine and taping trays, cannot be baked before unpacking.</caution>	VP15-107-2
Partial heating method	Terminal temperature: 300 °C or less Heat time: 3 seconds or less (for one side of a device)	-

- **Note** Maximum number of days during which the product can be stored at a temperature of 25 °C and a relative humidity of 65 % or less after dry-pack package is opened.
- Caution Do not apply two or more different soldering methods to one chip (except for partial heating method for terminal sections).

* APPENDIX A DEVELOPMENT TOOLS

The following development tools are available for system development using the μ PD784038. See also **(5)**.

(1) Language processing software

RA78K4	Assembler package for all 78K/IV series models	
СС78К4	C compiler package for all 78K/IV series models	
DF784038	Device file for μ PD784038 sub-series models	
CC78K4-L	C compiler library source file for all 78K/IV series models	

(2) PROM write tools

PG-1500	PROM programmer
PA-78P4026GC PA-78P4038GK PA-78P4026KK	Programmer adaptor, connects to PG-1500
PG-1500 controller	Control program for PG-1500

(3) Debugging tools

• When using the in-circuit emulator IE-78K4-NS

IE-78K4-NS	In-circuit emulator for all 78K/IV series models
IE-70000-MC-PS-B	Power supply unit for IE-78K4-NS
IE-70000-98-IF-C	Interface adapter when the PC-9800 series computer (other than a notebook) is used as the host machine
IE-70000-CD-IF	PC card and interface cable when a PC-9800 series notebook is used as the host machine
IE-70000-PC-IF-C	Interface adapter when the IBM PC/AT TM or compatible is used as the host machine
IE-784038-NS-EM1 ^{Note}	Emulation board for evaluating μ PD784038 sub-series models
NP-80GC	Emulation probe for 80-pin plastic QFP (GC-3B9 type)
NP-80GKNote	Emulation probe for 80-pin plastic TQFP (GK-BE9 type)
EV-9200GC-80	Socket for mounting on target system board made for 80-pin plastic QFP (GC-3B9 type)
TGK-080SDW	Adapter for mounting on target system board made for 80-pin plastic TQFP (fine pitch) (GK-BE9 type)
EV-9900	Tool used to remove the μ PD78P4038KK-T from the EV-9200GC-80
ID78K4-NS ^{Note}	Integrated debugger for IE-78K4-NS
SM78K4-NS	System simulator for all 78K/IV series models
DF784038	Device file for μ PD784038 sub-series models

Note Under development

• When using the in-circuit emulator IE-784000-R

IE-784000-R	In-circuit emulator for all 78K/IV series models
IE-70000-98-IF-B IE-70000-98-IF-C ^{Note}	Interface adapter when the PC-9800 series computer (other than a notebook) is used as the host machine
IE-70000-98N-IF	Interface adapter and cable when a PC-9800 series notebook is used as the host machine
IE-70000-PC-IF-B IE-70000-PC-IF-CNote	Interface adapter when the IBM PC/AT or compatible is used as the host machine
IE-78000-R-SV3	Interface adapter and cable when the EWS is used as the host machine
IE-784038-NS-EM1 Note IE-784038-R-EM1	Emulation board for evaluating μ PD784038 sub-series models
IE-78400-R-EM	Emulation board for all 78K/IV series models
IE-78K4-R-EX2Note	Conversion board for 80 pins to use the IE-784038-NS-EM1 on the IE-784000-R. The board is not needed when the conventional product IE-784038-R-EM1 is used.
EP-78230GC-R	Emulation probe for 80-pin plastic QFP (GC-3B9 type)
EP-78054GK-R	Emulation probe for 80-pin plastic TQFP (fine pitch) (GK-BE9 type) for all μ PD784038 sub-series
EV-9200GC-80	Socket for mounting on target system board made for 80-pin plastic QFP (GC-3B9 type)
TGK-080SDW	Adapter for mounting on target system board made for 80-pin plastic TQFP (fine pitch) (GK-BE9 type)
EV-9900	Tool used to remove the μ PD78P4038KK-T from the EV-9200GC-80
ID78K4	Integrated debugger for IE-784000-R
SM78K4	System simulator for all 78K/IV series models
DF784038	Device file for μ PD784038 sub-series models

Note Under development

(4) Real-time OS

RX78K/IV	Real-time OS for 78K/IV series models
MX78K4	OS for 78K/IV series models

(5) Notes when using development tools

- The ID78K-NS, ID78K4, and SM78K4 can be used in combination with the DF784038.
- The CC78K and RX78K/IV can be used in combination with the RA78K4 and DF784038.
- The NP-80GC is a product from Naito Densei Machida Mfg. Co., Ltd. (044-822-3813). Consult the NEC sales representative for purchasing.
- The TGK-080SDW is a product from TOKYO ELETECH CORPORATION.
 - Refer to: Daimaru Kogyo, Ltd.

Tokyo Electronic Components Division (03-3820-7112)

Osaka Electronic Components Division (06-244-6672)

• The host machines and operating systems corresponding to each software are shown below.

Host machine	PC	EWS
[OS]	PC-9800 Series [Windows TM]	HP9000 Series 700 [™] [HP-UX [™]]
	IBM PC/AT and compatibles [Windows]	SPARCstation [™] [SunOS [™]]
		NEWS [™] (RISC) [NEWS-OS [™]]
Software		
RA78K4	⊖Note	0
CC78K4	⊖ ^{Note}	0
PG-1500 controller	⊖Note	-
ID78K4-NS	0	-
ID78K4	0	0
SM78K4	0	-
RX78K/IV	ONote	0
MX78K4	⊖ ^{Note}	0

Note Software under MS-DOS

***** APPENDIX B RELATED DOCUMENTS

Documents Related to Devices

Desument nome	Document No.	
Document name	Japanese	English
μPD784031 Data Sheet	U11507J	U11507E
μPD7840335, 784036, 784037, 784038	U10847J	This manual
μPD78P4038 Data Sheet	U10848J	U10848E
μ PD784038, 784038Y Sub-Series User's Manual, Hardware	U11316J	U11316E
μ PD784038 Sub-Series Special Function Registers	U11090J	-
78K/IV Series User's Manual, Instruction	U10905J	U10905E
78K/IV Series Instruction Summary Sheet	U10594J	-
78K/IV Series Instruction Set	U10595J	-
78K/IV Series Application Note, Software Basic	U10095J	-

Documents Related to Development Tools (User's Manual)

Document name		Document No.	
		Japanese	English
RA78K4 Assembler Package	Operation	U11334J	U11334E
	Language	U11162J	U11162E
RA78K Series Structured Assembler Preprocessor		U11743J	U11743E
CC78K4 C Compiler	Operation	U11572J	U11572E
	Language	U11571J	U11571E
CC78K Series Library Source File		U12322J	U12322E
PG-1500 PROM Programmer		U11940J	U11940E
PG-1500 Controller PC-9800 Series (MS-DOS TM) Base		EEU-704	EEU-1291
PG-1500 Controller IBM PC Series (PC DOS™) Base		EEU-5008	U10540E
IE-78K4-NS		Under creation	To be created
IE-784000-R		U12903J	EEU-1534
IE-784038-NS-EM1		To be created	To be created
IE-784038-R-EM1		U11383J	U11383E
EP-78230		EEU-985	EEU-1515
EP-78054GK-R		EEU-932	EEU-1468
SM78K4 System Simulator Windows Base	Reference	U10093J	U10093E
SM78K Series System Simulator	External Parts User Open Interface Specifications	U10092J	U10092E
ID78K4 Integrated Debugger	Reference	U12796J	U12796E
ID78K4 Integrated Debugger Windows Base Reference		U10440J	U10440E
ID78K4 Integrated Debugger HP-UX, SunOS, NEW-OS Base Reference		U11960J	U11960E

Caution The above documents may be revised without notice. Use the latest versions when you design application systems.

Documents Related to Software to Be Incorporated into the Product (User's Manual)

Document name		Document No.	
		Japanese	English
78K/IV Series Real-Time OS	Basic	U10603J	U10603E
	Installation	U10604J	U10604E
	Debugger	U10364J	-
OS for 78K/IV Series MX78K4	Basic	U11779J	-

Other Documents

Document name	Document No.	
Document name	Japanese	English
IC PACKAGE MANUAL	C10943X	
Semiconductor Device Mounting Technology Manual	C10535J	C10535E
Quality Grades on NEC Semiconductor Device	C11531J	C11531E
NEC Semiconductor Device Reliability/Quality Control System	C10983J	C10983E
Guide to Prevent Damage for Semiconductor Devices by Electrostatic Discharge (ESD)	U11892J	E11892E
Semiconductor Device Quality Control/Reliability Handbook	C12769J	-
Guide for Products Related to Microcomputer: Other Companies	C11416J	-

Caution The above documents may be revised without notice. Use the latest versions when you design application systems.

NOTES FOR CMOS DEVICES -

1 PRECAUTION AGAINST ESD FOR SEMICONDUCTORS

Note: Strong electric field, when exposed to a MOS device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred. Environmental control must be adequate. When it is dry, humidifier should be used. It is recommended to avoid using insulators that easily build static electricity. Semiconductor devices must be stored and transported in an anti-static container, static shielding bag or conductive material. All test and measurement tools including work bench and floor should be grounded. The operator should be grounded using wrist strap. Semiconductor devices must not be touched with bare hands. Similar precautions need to be taken for PW boards with semiconductor devices on it.

(2) HANDLING OF UNUSED INPUT PINS FOR CMOS

Note: No connection for CMOS device inputs can be cause of malfunction. If no connection is provided to the input pins, it is possible that an internal input level may be generated due to noise, etc., hence causing malfunction. CMOS device behave differently than Bipolar or NMOS devices. Input levels of CMOS devices must be fixed high or low by using a pull-up or pull-down circuitry. Each unused pin should be connected to VDD or GND with a resistor, if it is considered to have a possibility of being an output pin. All handling related to the unused pins must be judged device by device and related specifications governing the devices.

③ STATUS BEFORE INITIALIZATION OF MOS DEVICES

Note: Power-on does not necessarily define initial status of MOS device. Production process of MOS does not define the initial operation status of the device. Immediately after the power source is turned ON, the devices with reset function have not yet been initialized. Hence, power-on does not guarantee out-pin levels, I/O settings or contents of registers. Device is not initialized until the reset signal is received. Reset operation must be executed immediately after power-on for devices having reset function.

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- Ordering information
- Product release schedule
- · Availability of related technical literature
- Development environment specifications (for example, specifications for third-party tools and components, host computers, power plugs, AC supply voltages, and so forth)
- Network requirements

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Anti-radioactive design is not implemented in this product.

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